

CC2652RB SimpleLink™ クリスタルレス BAW マルチプロトコル 2.4GHz ワイヤレス MCU

1 特長

- マイクロコントローラ
 - 強力な 48MHz Arm® Cortex®-M4F プロセッサ
 - EEMBC CoreMark® スコア: 148
 - 352KB のインシステム・プログラマブル・フラッシュ
 - プロトコルおよびライブラリ機能用の 256KB ROM
 - 8KB のキャッシュ SRAM (汎用 RAM としても使用可能)
 - 80KB の超低リーク SRAM。SRAM は動作の信頼性を高めるためパリティで保護。
 - 2 ピン cJTAG および JTAG デバッグ
 - OTA (Over-the-air) 更新をサポート
- 4KB の SRAM を搭載した超低消費電力センサ・コントローラ
 - センサ・データのサンプリング、保存、処理
 - システム CPU から独立して動作
 - 高速ウェイクアップにより低消費電力動作を実現
- TI-RTOS、ドライバ、ブートローダ、Bluetooth® 5.2 Low Energy コントローラ、IEEE 802.15.4 MAC を ROM に配置してアプリケーション・サイズを最適化
- RoHS 準拠のパッケージ
 - 7mm × 7mm の RGZ VQFN48 (31 GPIO)
- ペリフェラル
 - デジタル・ペリフェラルを任意の GPIO に接続可能
 - 4× 32 ビットまたは 8× 16 ビットの汎用タイマ
 - 12 ビット ADC、200k サンプル / 秒、8 チャンネル
 - 内部リファレンス電圧 DAC を搭載した 2 つのコンパレータ (連続時間 ×1、超低消費電力 ×1)
 - プログラマブルな電流ソース
 - UART ×2
 - SSI ×2 (SPI、MICROWIRE、TI)
 - I²C および I²S
 - リアルタイム・クロック (RTC)
 - AES 128 および 256 ビット暗号化アクセラレータ
 - ECC および RSA 公開鍵ハードウェア・アクセラレータ
 - SHA2 アクセラレータ (SHA-512 までのフル・スイート)
 - TRNG (True Random Number Generator)
 - 容量性センシング、最大 8 チャンネル
 - 温度およびバッテリー・モニタを内蔵
- 外部システム
 - 内蔵のバルク弾性波 (BAW) 共振器により、80μs の高速起動時間でシステムおよび RF 用の正確なクロックを生成
- オンチップの降圧型 DC/DC コンバータ
- 低消費電力
 - 広い電源電圧範囲
 - 通常動作: 1.8~3.8V
 - 外部レギュレータ・モード: 1.7~1.95V
 - アクティブ・モードの RX: 7.3mA
 - アクティブ・モードの TX (0dBm): 7.9mA
 - アクティブ・モードの TX (+5dBm): 10.2mA
 - アクティブ・モードの MCU 48MHz (CoreMark): 3.4mA (71μA/MHz)
 - センサ・コントローラ、低消費電力モード、2MHz、無限ループ動作: 30.8μA
 - センサ・コントローラ、アクティブ・モード、24MHz、無限ループ動作: 808μA
 - スタンバイ: 0.94μA (RTC 動作、80KB RAM および CPU を保持)
- 無線部
 - Bluetooth 5.2 Low Energy およびそれ以前の LE 仕様、IEEE 802.15.4 PHY および MAC と互換性がある 2.4GHz RF トランシーバ
 - 3 線式、2 線式、1 線式 PTA の共存メカニズム
 - 優れたレシーバ感度: 802.15.4 (2.4GHz) で -100dBm、Bluetooth 5 Low Energy Coded で -102dBm
 - 最大 +5dBm のプログラム可能な出力電力
 - 国際的な無線周波数規制への準拠を目標としたシステムに最適
 - EN 300 328、(欧州)
 - EN 300 440 カテゴリ 2
 - FCC CFR47 パート 15
 - ARIB STD-T66 (日本)
- ワイヤレス・プロトコル
 - Thread、Zigbee®、Bluetooth® 5.2 Low Energy、IEEE 802.15.4、IPv6 対応スマート・オブジェクト (6LoWPAN)、Wi-SUN™、独自システム、SimpleLink TI 15.4 スタック (2.4GHz)、DMM (ダイナミック・マルチプロトコル・マネージャ) ドライバ。
- 開発ツールとソフトウェア
 - [CC2652RB LaunchPad™ 開発キット](#)
 - [SimpleLink™ CC13x2 および CC26x2 ソフトウェア開発キット](#)
 - [SmartRF™ Studio](#) による単純な無線構成
 - [Sensor Controller Studio](#) により低消費電力のセンシング・アプリケーションを構築



2 アプリケーション

- 2400～2480MHz の ISM および SRD システム¹
(最小 4kHz の受信帯域幅)
- ビルディング・オートメーション
 - ビルディングのセキュリティ・システム – モーション検出器、電子スマート・ロック、ドアおよび窓センサ、ガレージ・ドア・システム、ゲートウェイ
 - HVAC – サーモスタット、ワイヤレス環境センサ、HVAC システム・コントローラ、ゲートウェイ
 - 防火システム – 煙および熱感知器、火災警報制御パネル (FACP)
 - ビデオ監視 – IP ネットワーク・カメラ
 - エレベータとエスカレータ – エレベータとエスカレータのエレベータ・メイン制御パネル
- グリッド・インフラストラクチャ
 - スマート・メータ – 水道メータ、ガス・メータ、電気メータ、ヒート・コスト・アラケータ
 - グリッド通信 – 無線通信 – 長距離センサ・アプリケーション
 - その他の代替エネルギー – 環境発電
- 産業用輸送 – アセット・トラッキング
- ファクトリ・オートメーションおよび制御
- 医療用
- 電子 POS (EPOS) – 電子棚札 (ESL)
- パーソナル・エレクトロニクス
 - 有線ネットワーク – 無線 LAN または Wi-Fi アクセス・ポイント、エッジ・ルータ、小規模企業向けルータ
 - 携帯型電子機器 – RF スマート遠隔制御
 - ホーム・シアターおよびエンターテインメント – スマート・スピーカ、スマート・ディスプレイ、セット・トップ・ボックス、ストリーミング・メディア・プレーヤ
 - ネットワーク接続の周辺機器 – 民生用ワイヤレス・モジュール、ワイヤレス・データ・アクセス・カード
 - ゲーム – 電子玩具とロボット玩具
 - ウェアラブル (非医療用) – スマート・トラッカー

3 概要

この SimpleLink™ CC2652RB デバイスは、テキサス・インスツルメンツの BAW (バルク弾性波) 共振器技術を組み込んだ業界初のマルチプロトコル 2.4GHz ワイヤレス・クリスタルレス・マイコン (MCU) です。本デバイスは Thread、Zigbee®、Bluetooth® 5.2 Low Energy、IEEE 802.15.4、IPv6 対応スマート・オブジェクト (6LoWPAN)、TI 15.4 スタック (2.4GHz) を含む独自システム、DMM (ダイナミック・マルチプロトコル・マネージャ) ソフトウェア・ドライバを使った同時マルチプロトコル動作をサポートしています。内蔵 BAW 共振器技術を使うと、レイテンシも周波数安定性も妥協することなく、外付け水晶振動子を不要にできます。このデバイスは、ビルディングのセキュリティ・システム、HVAC、医療、電動工具、有線ネットワーク、携帯型電子機器、ホーム・シアター / エンターテインメント、ネットワーク接続周辺機器市場向けの低消費電力の無線通信と先進センシングに最適化されています。

テキサス・インスツルメンツの BAW (バルク弾性波) 共振器技術の主な特長には以下が含まれます。

- 優れた周波数安定性 (温度 (-40°C～85°C) と動作電圧 (1.8V～3.8V) の全域で ±40PPM)、超低ジッタ、超低位相ノイズを実現し、各種無線通信規格のクロック要件を満たす圧倒的な RF 性能。
- 水晶振動子の調達を不要にし、外付け水晶振動子のレイアウトおよび組み立ての問題に起因するコストのかかる基板再設計および再認証を減らすことによる、効率的な開発および製造サイクル。
- 最適化された部品表 (BOM) と PCB 面積の低減 (平均 12%)。
- ほとんどの標準的な水晶振動子 (最長寿命 5 年) よりも優れた長期クロック安定性と経年性能 (10 年) により、長い製品ライフサイクルを実現。
- 堅牢な振動および機械的衝撃耐性 (外付け水晶振動子の 1/3 の PPM 変動) により、外付け水晶振動子の故障による製品交換コストを低減し、モータ、重機などの過酷な環境での動作を実現。
- 外部クロックの改ざんによるタイミング関連サイド・チャンネル攻撃の可能性を低減。

¹ サポートしているプロトコル規格、変調フォーマット、データ・レートの詳細については、RF コアを参照してください。

SimpleLink™ MCU プラットフォームの主な特長としては、以下に示すものがあります。

- SimpleLink™ CC13x2 および CC26x2 ソフトウェア開発キット (SDK) で幅広いプロトコル・スタックを柔軟にサポート。
- 0.84µA の小さいスタンバイ電流 (全 RAM 保持) によるバッテリー寿命が長いワイヤレス・アプリケーション。
- 産業用温度に対応し、85°C で 5.6µA の最小スタンバイ電流。
- 高速ウェークアップ機能を備えたプログラマブルな自律型超低消費電力センサ・コントローラ CPU による高度なセンシング。たとえば、このセンサ・コントローラは、1µA のシステム電流で 1Hz の ADC サンプルングが可能です。
- 潜在的な放射線イベントによるデータ破損を防止する常時オン SRAM パリティを備え、低い SER (ソフト・エラー・レート) FIT (Failure-in-time、故障率) により、産業用市場向けに中断のない長い動作寿命を実現。
- 複数の物理層と RF 規格をサポートする柔軟な低消費電力 RF トランシーバ機能を備えた、専用のソフトウェア定義無線コントローラ (Arm® Cortex®-M0)。

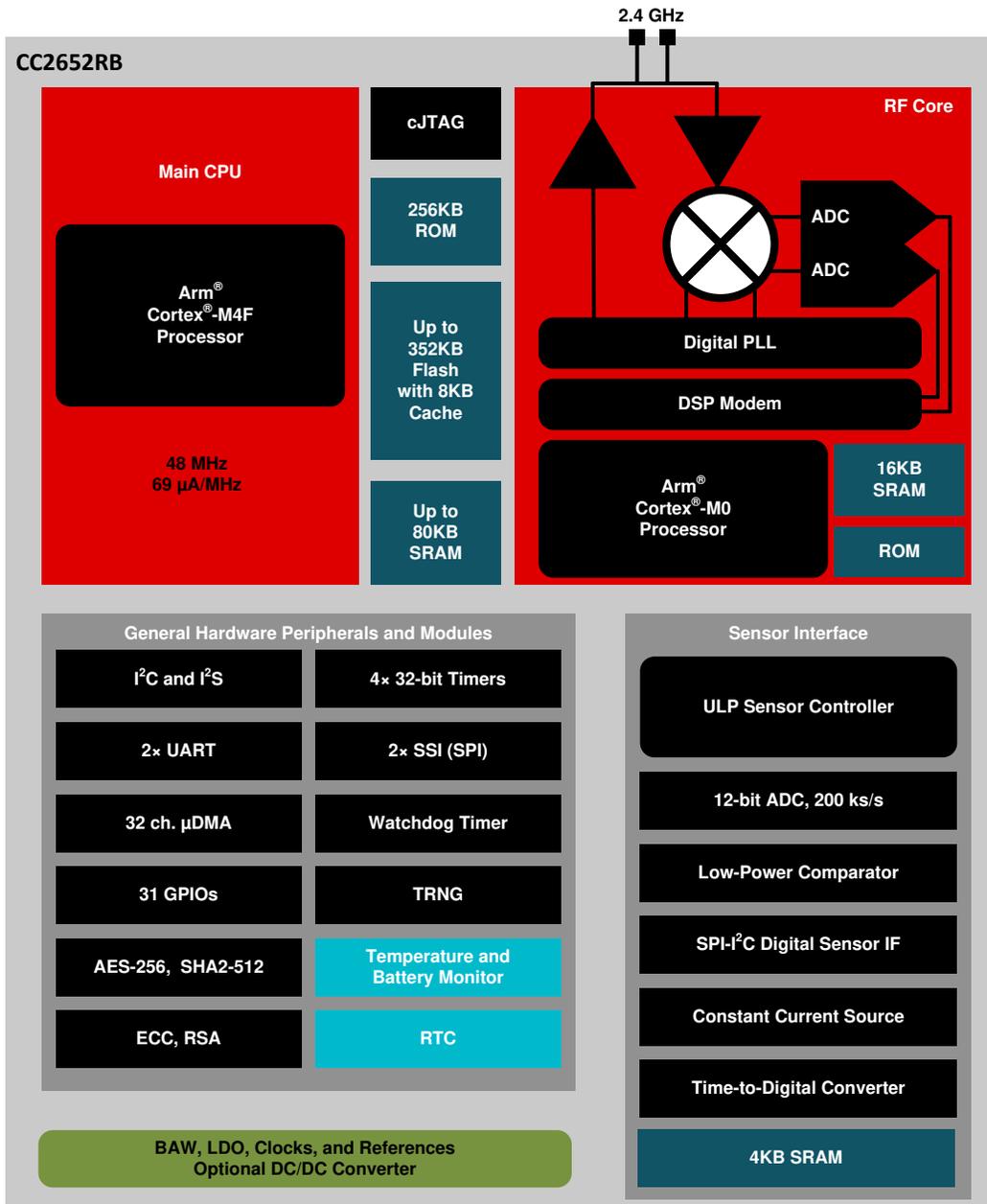
CC2652RB デバイスは SimpleLink™ MCU プラットフォームに属しています。本プラットフォームは、シングル・コア SDK (ソフトウェア開発キット) と豊富なツール・セットを備えた使いやすい共通の開発環境を共有する Wi-Fi®, Bluetooth Low Energy、Thread、Zigbee、Sub-1GHz MCU、ホスト MCU で構成されています。SimpleLink™ プラットフォームは一度で統合を実現でき、製品ラインアップのどのデバイスの組み合わせでも設計に追加できるので、設計要件変更の際もコードの 100% 再利用が可能です。詳細については、SimpleLink™ MCU プラットフォームを参照してください。

デバイス情報

部品番号 ⁽¹⁾	パッケージ	本体サイズ (公称)
CC2652RB1FRGZ	VQFN (48)	7.00mm × 7.00mm

- (1) 提供中の全デバイスに関する最新の製品、パッケージ、および注文情報については、[セクション 12](#) のパッケージ・オプションに関する付録、または [TI Web サイト](#) を参照してください。

4 Functional Block Diagram



4-1. CC2652RB Block Diagram

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5 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from August 12, 2020 to February 12, 2021 (from Revision C (August 2020) to Revision D (February 2021))

	Page
• 文書全体にわたって表、図、相互参照の採番方法を更新.....	1
• ドキュメント全体を通して Bluetooth 5.2 に更新.....	1
• セクション 1 「特長」の「無線」セクションのリストに 3 線、2 線、1 線 PTA 共存メカニズムを追加.....	1
• セクション 1 にワイヤレス・プロトコルを追加.....	1
• Changed the frequency of the input tone for 14-bit and 15-bit mode in セクション 8.15.1.1	25
• Added PTA description in セクション 9.3, Radio (RF Core)	50
• Added the paragraph that begins "Integrated matched filter-balun devices can be used..." in セクション 10.1, Reference Designs	57

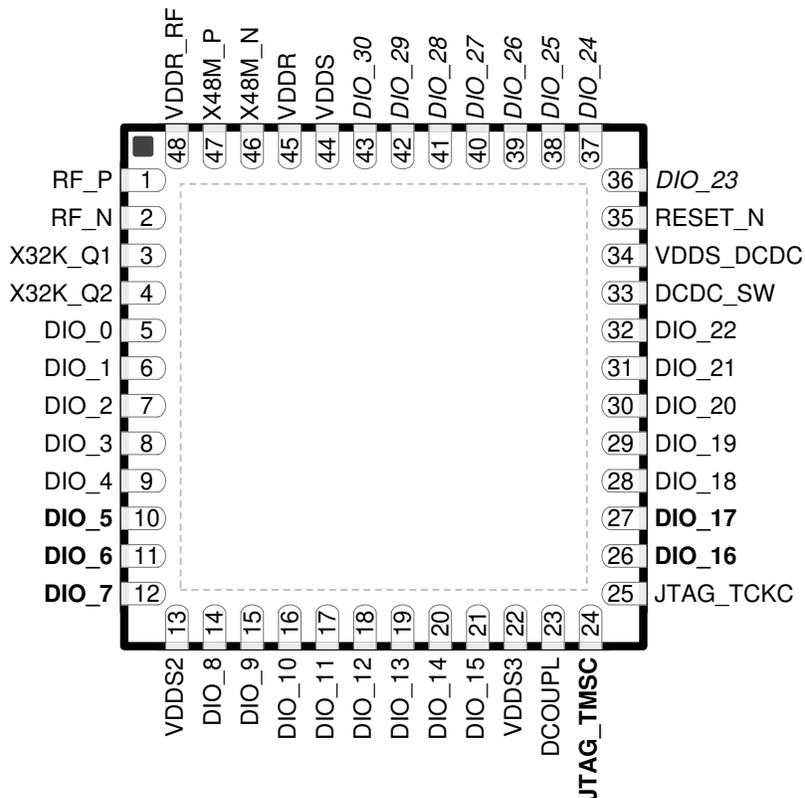
6 Device Comparison

表 6-1. Device Family Overview

DEVICE	RADIO SUPPORT	FLASH (KB)	RAM (KB)	GPIO	PACKAGE SIZE
CC1312R	Sub-1 GHz	352	80	30	RGZ (7-mm × 7-mm VQFN48)
CC1352P	Multiprotocol Sub-1 GHz Bluetooth 5.2 Low Energy Zigbee Thread 2.4 GHz proprietary FSK-based formats +20-dBm high-power amplifier	352	80	26	RGZ (7-mm × 7-mm VQFN48)
CC1352R	Multiprotocol Sub-1 GHz Bluetooth 5.2 Low Energy Zigbee Thread 2.4 GHz proprietary FSK-based formats	352	80	28	RGZ (7-mm × 7-mm VQFN48)
CC2642R	Bluetooth 5.2 Low Energy 2.4 GHz proprietary FSK-based formats	352	80	31	RGZ (7-mm × 7-mm VQFN48)
CC2642R-Q1	Bluetooth 5.2 Low Energy	352	80	31	RTC (7-mm × 7-mm VQFN48)
CC2652R	Multiprotocol Bluetooth 5.2 Low Energy Zigbee Thread 2.4 GHz proprietary FSK-based formats	352	80	31	RGZ (7-mm × 7-mm VQFN48)
CC2652RB	Multiprotocol Bluetooth 5.2 Low Energy Zigbee Thread 2.4 GHz proprietary FSK-based formats	352	80	31	RGZ (7-mm × 7-mm VQFN48)
CC2652P	Multiprotocol Bluetooth 5.2 Low Energy Zigbee Thread 2.4 GHz proprietary FSK-based formats +19.5-dBm high-power amplifier	352	80	26	RGZ (7-mm × 7-mm VQFN48)
CC1310	Sub-1 GHz	32–128	16–20	10–31	RGZ (7-mm × 7-mm VQFN48) RHB (5-mm × 5-mm VQFN32) RSM (4-mm × 4-mm VQFN32)
CC1350	Sub-1 GHz Bluetooth 4.2 Low Energy	128	20	10–31	RGZ (7-mm × 7-mm VQFN48) RHB (5-mm × 5-mm VQFN32) RSM (4-mm × 4-mm VQFN32)
CC2640R2F	Bluetooth 5.1 Low Energy 2.4 GHz proprietary FSK-based formats	128	20	10–31	RGZ (7-mm × 7-mm VQFN48) RHB (5-mm × 5-mm VQFN32) RSM (4-mm × 4-mm VQFN32) YFV (2.7-mm × 2.7-mm DSBGA34)
CC2640R2F-Q1	Bluetooth 5.1 Low Energy 2.4 GHz proprietary FSK-based formats	128	20	31	RGZ (7-mm × 7-mm VQFN48)

7 Terminal Configuration and Functions

7.1 Pin Diagram – RGZ Package (Top View)



7-1. RGZ (7-mm × 7-mm) Pinout, 0.5-mm Pitch (Top View)

The following I/O pins marked in 7-1 in **bold** have high-drive capabilities:

- Pin 10, **DIO_5**
- Pin 11, **DIO_6**
- Pin 12, **DIO_7**
- Pin 24, **JTAG_TMSC**
- Pin 26, **DIO_16**
- Pin 27, **DIO_17**

The following I/O pins marked in 7-1 in *italics* have analog capabilities:

- Pin 36, *DIO_23*
- Pin 37, *DIO_24*
- Pin 38, *DIO_25*
- Pin 39, *DIO_26*
- Pin 40, *DIO_27*
- Pin 41, *DIO_28*
- Pin 42, *DIO_29*
- Pin 43, *DIO_30*

7.2 Signal Descriptions – RGZ Package

表 7-1. Signal Descriptions – RGZ Package

PIN		I/O	TYPE	DESCRIPTION
NAME	NO.			
DCDC_SW	33	—	Power	Output from internal DC/DC converter. Tie to ground for external regulator mode (1.7-V to 1.95-V operation). ⁽¹⁾
DCOUPPL	23	—	Power	For decoupling of internal 1.27 V regulated digital-supply ⁽²⁾
DIO_0	5	I/O	Digital	GPIO
DIO_1	6	I/O	Digital	GPIO
DIO_2	7	I/O	Digital	GPIO
DIO_3	8	I/O	Digital	GPIO
DIO_4	9	I/O	Digital	GPIO
DIO_5	10	I/O	Digital	GPIO, high-drive capability
DIO_6	11	I/O	Digital	GPIO, high-drive capability
DIO_7	12	I/O	Digital	GPIO, high-drive capability
DIO_8	14	I/O	Digital	GPIO
DIO_9	15	I/O	Digital	GPIO
DIO_10	16	I/O	Digital	GPIO
DIO_11	17	I/O	Digital	GPIO
DIO_12	18	I/O	Digital	GPIO
DIO_13	19	I/O	Digital	GPIO
DIO_14	20	I/O	Digital	GPIO
DIO_15	21	I/O	Digital	GPIO
DIO_16	26	I/O	Digital	GPIO, JTAG_TDO, high-drive capability
DIO_17	27	I/O	Digital	GPIO, JTAG_TDI, high-drive capability
DIO_18	28	I/O	Digital	GPIO
DIO_19	29	I/O	Digital	GPIO
DIO_20	30	I/O	Digital	GPIO
DIO_21	31	I/O	Digital	GPIO
DIO_22	32	I/O	Digital	GPIO
DIO_23	36	I/O	Digital or Analog	GPIO, analog capability
DIO_24	37	I/O	Digital or Analog	GPIO, analog capability
DIO_25	38	I/O	Digital or Analog	GPIO, analog capability
DIO_26	39	I/O	Digital or Analog	GPIO, analog capability
DIO_27	40	I/O	Digital or Analog	GPIO, analog capability
DIO_28	41	I/O	Digital or Analog	GPIO, analog capability
DIO_29	42	I/O	Digital or Analog	GPIO, analog capability
DIO_30	43	I/O	Digital or Analog	GPIO, analog capability
EGP	—	—	GND	Ground – exposed ground pad ⁽³⁾
JTAG_TMISC	24	I/O	Digital	JTAG TMISC, high-drive capability
JTAG_TCKC	25	I	Digital	JTAG TCKC
RESET_N	35	I	Digital	Reset, active low. No internal pullup resistor
RF_P	1	—	RF	Positive RF input signal to LNA during RX Positive RF output signal from PA during TX
RF_N	2	—	RF	Negative RF input signal to LNA during RX Negative RF output signal from PA during TX

表 7-1. Signal Descriptions – RGZ Package (continued)

PIN		I/O	TYPE	DESCRIPTION
NAME	NO.			
VDDR	45	—	Power	Internal supply, must be powered from the internal DC/DC converter or the internal LDO. For external regulator mode (1.7-V to 1.95-V operation), connect to external regulator and internal DC-DC cannot be used. (2) (4) (6)
VDDR_RF	48	—	Power	Internal supply, must be powered from the internal DC/DC converter or the internal LDO (2) (5) (6)
VDDS	44	—	Power	1.8-V to 3.8-V main chip supply. For external regulator mode (1.7-V to 1.95-V operation), connect to external regulator and internal DC-DC cannot be used. (1)
VDDS2	13	—	Power	1.8-V to 3.8-V DIO supply (1)
VDDS3	22	—	Power	1.8-V to 3.8-V DIO supply (1)
VDDS_DCDC	34	—	Power	1.8-V to 3.8-V DC/DC converter supply. Tie to ground for external regulator mode (1.7-V to 1.95-V operation).
X48M_N	46	—	Analog	48-MHz crystal oscillator pin 1. Do not connect if not in use. (Optional) (7)
X48M_P	47	—	Analog	48-MHz crystal oscillator pin 2. Do not connect if not in use. (Optional) (7)
X32K_Q1	3	—	Analog	32-kHz crystal oscillator pin 1
X32K_Q2	4	—	Analog	32-kHz crystal oscillator pin 2

- (1) For more details, see technical reference manual listed in セクション 11.2.
(2) Do not supply external circuitry from this pin.
(3) EGP is the only ground connection for the device. Good electrical connection to device ground on printed circuit board (PCB) is imperative for proper device operation.
(4) If internal DC/DC converter is not used, this pin is supplied internally from the main LDO.
(5) If internal DC/DC converter is not used, this pin must be connected to VDDR for supply from the main LDO.
(6) Output from internal DC/DC and LDO is trimmed to 1.68 V.
(7) The X48M_N and X48M_P pins can be used to connect an external 48-MHz crystal. This clock can be used instead of the internal BAW clock. However, it is not required for the device standard operation.

7.3 Connections for Unused Pins and Modules

表 7-2. Connections for Unused Pins

FUNCTION	SIGNAL NAME	PIN NUMBER	ACCEPTABLE PRACTICE (1)	PREFERRED PRACTICE (1)
GPIO	DIO_n	5–12	NC or GND	NC
		14–21		
		26–32		
		36–43		
32.768-kHz crystal	X32K_Q1	3	NC or GND	NC
	X32K_Q2	4		
DC/DC converter (2)	DCDC_SW	33	NC	NC
	VDDS_DCDC	34	VDDS (GND) (3)	VDDS (GND) (3)
48-MHz crystal	X48M_N	46	NC	NC
	X48M_P	47	NC	NC

- (1) NC = No connect
(2) When the DC/DC converter is not used, the inductor between DCDC_SW and VDDR can be removed. VDDR and VDDR_RF must still be connected and the 22 uF DCDC capacitor must be kept on the VDDR net.
(3) When operating in external regulator mode.

8 Specifications

8.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)^{(1) (2)}

		MIN	MAX	UNIT
V _{DD} S ⁽³⁾	Supply voltage	-0.3	4.1	V
V _{DD} S and V _{DD} R ⁽⁵⁾	Supply voltage (External regulator mode)	-0.3	2.25	V
	Voltage on any digital pin ⁽⁴⁾	-0.3	V _{DD} S + 0.3, max 4.1	V
	Voltage on crystal oscillator pins, X32K_Q1, X32K_Q2, X48M_N and X48M_P	-0.3	V _{DD} R + 0.3, max 2.25	V
V _{in}	Voltage on ADC input	Voltage scaling enabled	V _{DD} S	V
		Voltage scaling disabled, internal reference	1.49	
		Voltage scaling disabled, V _{DD} S as reference	V _{DD} S / 2.9	
			5	dBm
T _{stg}	Storage temperature	-40	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to ground, unless otherwise noted.
- (3) V_{DD}S_DCDC, V_{DD}S2 and V_{DD}S3 must be at the same potential as V_{DD}S.
- (4) Including analog capable DIOs.
- (5) V_{DD}R, V_{DD}S, V_{DD}S2 and V_{DD}S3 must be at the same potential.

8.2 ESD Ratings

			VALUE	UNIT	
V _{ESD}	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	All pins	±2000	V
		Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002 ⁽²⁾	All pins	±500	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process

8.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
Operating ambient temperature		-40	85	°C
Operating supply voltage (V _{DD} S and V _{DD} R), external regulator mode	For operation in 1.8-V systems (V _{DD} S and V _{DD} R pins connected on PCB, internal DC-DC cannot be used)	1.7	1.95	V
Operating supply voltage (V _{DD} S)		1.8	3.8	V
Rising supply voltage slew rate		0	100	mV/μs
Falling supply voltage slew rate ⁽¹⁾		0	20	mV/μs

- (1) For small coin-cell batteries, with high worst-case end-of-life equivalent source resistance, a 22-μF V_{DD}S input capacitor must be used to ensure compliance with this slew rate.

8.4 Power Supply and Modules

over operating free-air temperature range (unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNIT
VDDS Power-on-Reset (POR) threshold			1.1 - 1.55		V
VDDS Brown-out Detector (BOD) ⁽¹⁾	Rising threshold		1.77		V
VDDS Brown-out Detector (BOD) External regulator mode	Rising threshold		1.64		V
VDDS Brown-out Detector (BOD), before initial boot ⁽²⁾	Rising threshold		1.70		V
VDDS Brown-out Detector (BOD) ⁽¹⁾	Falling threshold		1.75		V
VDDS Brown-out Detector (BOD) External regulator mode	Falling threshold		1.63		V

(1) For boost mode (VDDR = 1.95 V), TI drivers software initialization will trim VDDS BOD limits to maximum (approximately 2.0 V)

(2) Brown-out Detector is trimmed at initial boot, value is kept until device is reset by a POR reset or the RESET_N pin

8.5 Power Consumption - Power Modes

When measured on the CC26x2RBEM-7ID reference design with $T_c = 25^\circ\text{C}$, $V_{\text{DDS}} = 3.0\text{ V}$ with DC/DC enabled unless otherwise noted.

PARAMETER	TEST CONDITIONS		TYP	UNIT
Core Current Consumption				
I_{core}	Reset and Shutdown	Reset. RESET_N pin asserted or VDDS below power-on-reset threshold	150	nA
		Shutdown. No clocks running, no retention	150	
	Standby without cache retention	RTC running, CPU, 80KB RAM and (partial) register retention. RCOSC_LF	0.94	μA
		RTC running, CPU, 80KB RAM and (partial) register retention. XOSC_LF	1.09	
	Standby with cache retention	RTC running, CPU, 80KB RAM and (partial) register retention. RCOSC_LF	3.2	μA
		RTC running, CPU, 80KB RAM and (partial) register retention. XOSC_LF	3.3	
	Idle	Supply Systems and RAM powered RCOSC_HF	675	μA
Active	MCU running CoreMark at 48 MHz RCOSC_HF	3.39	mA	
Peripheral Current Consumption				
I_{peri}	Peripheral power domain	Delta current with domain enabled	97.7	μA
	Serial power domain	Delta current with domain enabled	7.2	
	RF Core	Delta current with power domain enabled, clock enabled, RF core idle	210.9	
	μDMA	Delta current with clock enabled, module is idle	63.9	
	Timers	Delta current with clock enabled, module is idle ⁽³⁾	81.0	
	I2C	Delta current with clock enabled, module is idle	10.1	
	I2S	Delta current with clock enabled, module is idle	26.3	
	SSI	Delta current with clock enabled, module is idle	82.9	
	UART	Delta current with clock enabled, module is idle ⁽¹⁾	167.5	
	CRYPTO (AES)	Delta current with clock enabled, module is idle ⁽²⁾	25.6	
	PKA	Delta current with clock enabled, module is idle	84.7	
TRNG	Delta current with clock enabled, module is idle	35.6		
Sensor Controller Engine Consumption				

8.5 Power Consumption - Power Modes (continued)

When measured on the CC26x2RBEM-7ID reference design with $T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$ with DC/DC enabled unless otherwise noted.

PARAMETER		TEST CONDITIONS	TYP	UNIT
I _{SCE}	Active mode	24 MHz, infinite loop	808.5	μA
	Low-power mode	2 MHz, infinite loop	30.1	

- (1) Only one UART running
- (2) Only one SSI running
- (3) Only one GPTimer running

8.6 Power Consumption - Radio Modes

When measured on the CC26x2RBEM-7ID reference design with $T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.6\text{ V}$ with DC/DC enabled unless otherwise noted.

PARAMETER		TEST CONDITIONS	TYP	UNIT
	Radio receive current	2440 MHz	7.3	mA
	Radio transmit current	0 dBm output power setting 2440 MHz	7.9	mA
		+5 dBm output power setting 2440 MHz	10.2	mA

8.7 Nonvolatile (Flash) Memory Characteristics

Over operating free-air temperature range and $V_{DD5} = 3.0\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Flash sector size				8		KB
Supported flash erase cycles before failure, full bank ⁽¹⁾ ⁽⁵⁾			30			k Cycles
Supported flash erase cycles before failure, single sector ⁽²⁾			60			k Cycles
Maximum number of write operations per row before sector erase ⁽³⁾					83	Write Operations
Flash retention		105 °C	11.4			Years at 105 °C
Flash sector erase current		Average delta current		10.7		mA
Flash sector erase time ⁽⁴⁾		Zero cycles		10		ms
Flash write current		Average delta current, 4 bytes at a time		6.2		mA
Flash write time ⁽⁴⁾		4 bytes at a time		21.6		μs

- (1) A full bank erase is counted as a single erase cycle on each sector
- (2) Up to 4 customer-designated sectors can be individually erased an additional 30k times beyond the baseline bank limitation of 30k cycles
- (3) Each wordline is 2048 bits (or 256 bytes) wide. This limitation corresponds to sequential memory writes of 4 (3.1) bytes minimum per write over a whole wordline. If additional writes to the same wordline are required, a sector erase is required once the maximum number of write operations per row is reached.
- (4) This number is dependent on Flash aging and increases over time and erase cycles
- (5) Aborting flash during erase or program modes is not a safe operation.

8.8 Thermal Resistance Characteristics

THERMAL METRIC ⁽¹⁾		PACKAGE		UNIT
		RGZ (VQFN)		
		48 PINS		
R _{θJA}	Junction-to-ambient thermal resistance	23.4		°C/W ⁽²⁾
R _{θJC(top)}	Junction-to-case (top) thermal resistance	13.3		°C/W ⁽²⁾

8.8 Thermal Resistance Characteristics (continued)

THERMAL METRIC ⁽¹⁾		PACKAGE	
		RGZ (VQFN)	UNIT
		48 PINS	
R _{θJB}	Junction-to-board thermal resistance	8.0	°C/W ⁽²⁾
Ψ _{JT}	Junction-to-top characterization parameter	0.1	°C/W ⁽²⁾
Ψ _{JB}	Junction-to-board characterization parameter	7.9	°C/W ⁽²⁾
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	1.7	°C/W ⁽²⁾

(1) For more information about traditional and new thermal metrics, see [Semiconductor and IC Package Thermal Metrics](#).

(2) °C/W = degrees Celsius per watt.

8.9 RF Frequency Bands

Over operating free-air temperature range (unless otherwise noted).

PARAMETER	MIN	TYP	MAX	UNIT
Frequency bands	2360		2500	MHz

8.10 Bluetooth Low Energy - Receive (RX)

When measured on the CC26x2RBEM-71D reference design with T_c = 25 °C, V_{DD5} = 3.0 V, f_{RF} = 2440 MHz with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path.

All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
125 kbps (LE Coded)					
Receiver sensitivity	Differential mode. BER = 10 ⁻³		-102		dBm
Receiver saturation	Differential mode. BER = 10 ⁻³		>5		dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency		> (-300 / 300)		kHz
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (37-byte packets)		> (-240 / 240)		ppm
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (255-byte packets)		> (-125 / 125)		ppm
Co-channel rejection ⁽¹⁾	Wanted signal at -79 dBm, modulated interferer in channel, BER = 10 ⁻³		-1.5		dB
Selectivity, ±1 MHz ⁽¹⁾	Wanted signal at -79 dBm, modulated interferer at ±1 MHz, BER = 10 ⁻³ , measured at input level -82 dBm		8 / 2 ⁽²⁾		dB
Selectivity, ±2 MHz ⁽¹⁾	Wanted signal at -79 dBm, modulated interferer at ±2 MHz, BER = 10 ⁻³ , measured at input level -82 dBm		44 / 39 ⁽²⁾		dB
Selectivity, ±3 MHz ⁽¹⁾	Wanted signal at -79 dBm, modulated interferer at ±3 MHz, BER = 10 ⁻³ , measured at input level -82 dBm		46 / 44 ⁽²⁾		dB
Selectivity, ±4 MHz ⁽¹⁾	Wanted signal at -79 dBm, modulated interferer at ±4 MHz, BER = 10 ⁻³ , measured at input level -82 dBm		44 / 46 ⁽²⁾		dB
Selectivity, ±6 MHz ⁽¹⁾	Wanted signal at -79 dBm, modulated interferer at ≥ ±6 MHz, BER = 10 ⁻³ , measured at input level -82 dBm		48 / 44 ⁽²⁾		dB

8.10 Bluetooth Low Energy - Receive (RX) (continued)

When measured on the CC26x2RBEM-71D reference design with $T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$, $f_{RF} = 2440\text{ MHz}$ with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path.

All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Selectivity, $\pm 7\text{ MHz}$	Wanted signal at -79 dBm , modulated interferer at $\geq \pm 7\text{ MHz}$, BER = 10^{-3} , measured at input level -82 dBm		51 / 45 ⁽²⁾		dB
Selectivity, Image frequency ⁽¹⁾	Wanted signal at -79 dBm , modulated interferer at image frequency, BER = 10^{-3} , measured at input level -82 dBm		39		dB
Selectivity, Image frequency $\pm 1\text{ MHz}$ ⁽¹⁾	Note that Image frequency + 1 MHz is the Co-channel -1 MHz . Wanted signal at -79 dBm , modulated interferer at $\pm 1\text{ MHz}$ from image frequency, BER = 10^{-3} , measured at input level -82 dBm		2 / 44 ⁽²⁾		dB
500 kbps (LE Coded)					
Receiver sensitivity	Differential mode. BER = 10^{-3}		-100		dBm
Receiver saturation	Differential mode. BER = 10^{-3}		> 5		dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency		$> (-300 / 300)$		kHz
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (37-byte packets)		$> (-450 / 450)$		ppm
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (255-byte packets)		$> (-175 / 175)$		ppm
Co-channel rejection ⁽¹⁾	Wanted signal at -72 dBm , modulated interferer in channel, BER = 10^{-3}		-3.5		dB
Selectivity, $\pm 1\text{ MHz}$ ⁽¹⁾	Wanted signal at -72 dBm , modulated interferer at $\pm 1\text{ MHz}$, BER = 10^{-3} , measured at input level -75 dBm		5 / -1 ⁽²⁾		dB
Selectivity, $\pm 2\text{ MHz}$ ⁽¹⁾	Wanted signal at -72 dBm , modulated interferer at $\pm 2\text{ MHz}$, BER = 10^{-3} , measured at input level -75 dBm		44 / 37 ⁽²⁾		dB
Selectivity, $\pm 3\text{ MHz}$ ⁽¹⁾	Wanted signal at -72 dBm , modulated interferer at $\pm 3\text{ MHz}$, BER = 10^{-3} , measured at input level -75 dBm		46 / 46 ⁽²⁾		dB
Selectivity, $\pm 4\text{ MHz}$ ⁽¹⁾	Wanted signal at -72 dBm , modulated interferer at $\pm 4\text{ MHz}$, BER = 10^{-3} , measured at input level -75 dBm		45 / 47 ⁽²⁾		dB
Selectivity, $\pm 6\text{ MHz}$ ⁽¹⁾	Wanted signal at -72 dBm , modulated interferer at $\geq \pm 6\text{ MHz}$, BER = 10^{-3} , measured at input level -75 dBm		46 / 45 ⁽²⁾		dB
Selectivity, $\pm 7\text{ MHz}$	Wanted signal at -72 dBm , modulated interferer at $\geq \pm 7\text{ MHz}$, BER = 10^{-3} , measured at input level -75 dBm		49 / 45 ⁽²⁾		dB
Selectivity, Image frequency ⁽¹⁾	Wanted signal at -72 dBm , modulated interferer at image frequency, BER = 10^{-3} , measured at input level -75 dBm		37		dB
Selectivity, Image frequency $\pm 1\text{ MHz}$ ⁽¹⁾	Note that Image frequency + 1 MHz is the Co-channel -1 MHz . Wanted signal at -72 dBm , modulated interferer at $\pm 1\text{ MHz}$ from image frequency, BER = 10^{-3} , measured at input level -75 dBm		-1 / 46 ⁽²⁾		dB
1 Mbps (LE 1M)					

8.10 Bluetooth Low Energy - Receive (RX) (continued)

When measured on the CC26x2RBEM-71D reference design with $T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$, $f_{RF} = 2440\text{ MHz}$ with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path.

All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Receiver sensitivity	Differential mode. BER = 10^{-3}		-97		dBm
Receiver saturation	Differential mode. BER = 10^{-3}		> 5		dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency		> (-350 / 350)		kHz
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (37-byte packets)		> (-750 / 750)		ppm
Co-channel rejection ⁽¹⁾	Wanted signal at -67 dBm, modulated interferer in channel, BER = 10^{-3}		-6		dB
Selectivity, $\pm 1\text{ MHz}$ ⁽¹⁾	Wanted signal at -67 dBm, modulated interferer at $\pm 1\text{ MHz}$, BER = 10^{-3} , measured at input level -70 dBm		7 / 4 ⁽²⁾		dB
Selectivity, $\pm 2\text{ MHz}$ ⁽¹⁾	Wanted signal at -67 dBm, modulated interferer at $\pm 2\text{ MHz}$, BER = 10^{-3} , measured at input level -70 dBm		39 / 33 ⁽²⁾		dB
Selectivity, $\pm 3\text{ MHz}$ ⁽¹⁾	Wanted signal at -67 dBm, modulated interferer at $\pm 3\text{ MHz}$, BER = 10^{-3} , measured at input level -70 dBm		36 / 41 ⁽²⁾		dB
Selectivity, $\pm 4\text{ MHz}$ ⁽¹⁾	Wanted signal at -67 dBm, modulated interferer at $\pm 4\text{ MHz}$, BER = 10^{-3} , measured at input level -70 dBm		36 / 45 ⁽²⁾		dB
Selectivity, $\pm 5\text{ MHz}$ or more ⁽¹⁾	Wanted signal at -67 dBm, modulated interferer at $\geq \pm 5\text{ MHz}$, BER = 10^{-3} , measured at input level -70 dBm		40		dB
Selectivity, image frequency ⁽¹⁾	Wanted signal at -67 dBm, modulated interferer at image frequency, BER = 10^{-3} , measured at input level -70 dBm		33		dB
Selectivity, image frequency $\pm 1\text{ MHz}$ ⁽¹⁾	Note that Image frequency + 1 MHz is the Co-channel -1 MHz. Wanted signal at -67 dBm, modulated interferer at $\pm 1\text{ MHz}$ from image frequency, BER = 10^{-3} , measured at input level -70 dBm		4 / 41 ⁽²⁾		dB
Out-of-band blocking ⁽³⁾	30 MHz to 2000 MHz		-10		dBm
Out-of-band blocking	2003 MHz to 2399 MHz		-18		dBm
Out-of-band blocking	2484 MHz to 2997 MHz		-12		dBm
Out-of-band blocking	3000 MHz to 12.75 GHz		-2		dBm
Intermodulation	Wanted signal at 2402 MHz, -64 dBm. Two interferers at 2405 and 2408 MHz respectively, at the given power level		-42		dBm
Spurious emissions, 30 to 1000 MHz ⁽⁴⁾	Measurement in a 50- Ω single-ended load.		< -59		dBm
Spurious emissions, 1 to 12.75 GHz ⁽⁴⁾	Measurement in a 50 Ω single-ended load.		< -47		dBm
RSSI dynamic range			70		dB
RSSI accuracy			± 4		dB
2 Mbps (LE 2M)					
Receiver sensitivity	Differential mode. Measured at SMA connector, BER = 10^{-3}		-92		dBm

8.10 Bluetooth Low Energy - Receive (RX) (continued)

When measured on the CC26x2RBEM-71D reference design with $T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$, $f_{RF} = 2440\text{ MHz}$ with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path.

All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Receiver saturation	Differential mode. Measured at SMA connector, BER = 10^{-3}		> 5		dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency		> (-500 / 500)		kHz
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (37-byte packets)		> (-700 / 750)		ppm
Co-channel rejection ⁽¹⁾	Wanted signal at -67 dBm, modulated interferer in channel, BER = 10^{-3}		-7		dB
Selectivity, $\pm 2\text{ MHz}$ ⁽¹⁾	Wanted signal at -67 dBm, modulated interferer at $\pm 2\text{ MHz}$, Image frequency is at -2 MHz, BER = 10^{-3} , measured at input level -70 dBm		8 / 4 ⁽²⁾		dB
Selectivity, $\pm 4\text{ MHz}$ ⁽¹⁾	Wanted signal at -67 dBm, modulated interferer at $\pm 4\text{ MHz}$, BER = 10^{-3} , measured at input level -70 dBm		36 / 36 ⁽²⁾		dB
Selectivity, $\pm 6\text{ MHz}$ ⁽¹⁾	Wanted signal at -67 dBm, modulated interferer at $\pm 6\text{ MHz}$, BER = 10^{-3} , measured at input level -70 dBm		37 / 36 ⁽²⁾		dB
Selectivity, image frequency ⁽¹⁾	Wanted signal at -67 dBm, modulated interferer at image frequency, BER = 10^{-3} , measured at input level -70 dBm		4		dB
Selectivity, image frequency $\pm 2\text{ MHz}$ ⁽¹⁾	Note that Image frequency + 2 MHz is the Co-channel. Wanted signal at -67 dBm, modulated interferer at $\pm 2\text{ MHz}$ from image frequency, BER = 10^{-3} , measured at input level -70 dBm		-7 / 36 ⁽²⁾		dB
Out-of-band blocking ⁽³⁾	30 MHz to 2000 MHz		-16		dBm
Out-of-band blocking	2003 MHz to 2399 MHz		-21		dBm
Out-of-band blocking	2484 MHz to 2997 MHz		-15		dBm
Out-of-band blocking	3000 MHz to 12.75 GHz		-12		dBm
Intermodulation	Wanted signal at 2402 MHz, -64 dBm. Two interferers at 2408 and 2414 MHz respectively, at the given power level		-38		dBm

(1) Numbers given as I/C dB

(2) X / Y, where X is +N MHz and Y is -N MHz

(3) Excluding one exception at $F_{wanted} / 2$, per Bluetooth Specification

(4) Suitable for systems targeting compliance with worldwide radio-frequency regulations ETSI EN 300 328 and EN 300 440 Class 2 (Europe), FCC CFR47 Part 15 (US), and ARIB STD-T66 (Japan)

8.11 Bluetooth Low Energy - Transmit (TX)

When measured on the CC26x2RBEM-71D reference design with $T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$, $f_{RF} = 2440\text{ MHz}$ with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path.

All measurements are performed conducted.

PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
General Parameters						
Max output power	Differential mode, delivered to a single-ended 50 Ω load through a balun	Differential mode, delivered to a single-ended 50 Ω load through a balun		5		dBm

8.11 Bluetooth Low Energy - Transmit (TX) (continued)

When measured on the CC26x2RBEM-71D reference design with $T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$, $f_{RF} = 2440\text{ MHz}$ with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path.

All measurements are performed conducted.

PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Output power programmable range	Differential mode, delivered to a single-ended 50 Ω load through a balun			26		dB
Spurious emissions and harmonics						
Spurious emissions ⁽¹⁾	f < 1 GHz, outside restricted bands	+5 dBm setting		< -36		dBm
	f < 1 GHz, restricted bands ETSI	+5 dBm setting		< -54		dBm
	f < 1 GHz, restricted bands FCC	+5 dBm setting		< -55		dBm
	f > 1 GHz, including harmonics	+5 dBm setting		< -42		dBm
Harmonics ⁽¹⁾	Second harmonic	+5 dBm setting		< -42		dBm
	Third harmonic	+5 dBm setting		< -42		dBm

(1) Suitable for systems targeting compliance with worldwide radio-frequency regulations ETSI EN 300 328 and EN 300 440 Class 2 (Europe), FCC CFR47 Part 15 (US), and ARIB STD-T66 (Japan).

8.12 Zigbee and Thread - IEEE 802.15.4-2006 2.4 GHz (OQPSK DSSS1:8, 250 kbps) - TX

When measured on the CC26x2RBEM-71D reference design with $T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$, $f_{RF} = 2440\text{ MHz}$ with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path.

All measurements are performed conducted.

PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
General Parameters						
Max output power	Differential mode, delivered to a single-ended 50- Ω load through a balun			5		dBm
Output power programmable range	Differential mode, delivered to a single-ended 50- Ω load through a balun			26		dB
Spurious emissions and harmonics						
Spurious emissions ⁽¹⁾ ⁽²⁾	f < 1 GHz, outside restricted bands	+5 dBm setting		< -36		dBm
	f < 1 GHz, restricted bands ETSI			< -47		dBm
	f < 1 GHz, restricted bands FCC			< -55		dBm
	f > 1 GHz, including harmonics			< -42		dBm
Harmonics ⁽¹⁾	Second harmonic			< -42		dBm
	Third harmonic			< -42		dBm
IEEE 802.15.4-2006 2.4 GHz (OQPSK DSSS1:8, 250 kbps)						
Error vector magnitude	+5 dBm setting			2		%

(1) Suitable for systems targeting compliance with worldwide radio-frequency regulations ETSI EN 300 328 and EN 300 440 Class 2 (Europe), FCC CFR47 Part 15 (US), and ARIB STD-T66 (Japan).

(2) To ensure margins for passing FCC band edge requirements at 2483.5 MHz, a lower than maximum output-power setting or less than 100% duty cycle may be used when operating at 2480 MHz.

8.13 Zigbee and Thread - IEEE 802.15.4-2006 2.4 GHz (OQPSK DSSS1:8, 250 kbps) - RX

When measured on the CC26x2RBEM-7ID reference design with $T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$, $f_{RF} = 2440\text{ MHz}$ with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path.

All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Receiver sensitivity	PER = 1%		-100		dBm
Receiver saturation	PER = 1%		> 5		dBm
Adjacent channel rejection	Wanted signal at -82 dBm, modulated interferer at $\pm 5\text{ MHz}$, PER = 1%		36		dB
Alternate channel rejection	Wanted signal at -82 dBm, modulated interferer at $\pm 10\text{ MHz}$, PER = 1%		57		dB
Channel rejection, $\pm 15\text{ MHz}$ or more	Wanted signal at -82 dBm, undesired signal is IEEE 802.15.4 modulated channel, stepped through all channels 2405 to 2480 MHz, PER = 1%		59		dB
Blocking and desensitization, 5 MHz from upper band edge	Wanted signal at -97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%		57		dB
Blocking and desensitization, 10 MHz from upper band edge	Wanted signal at -97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%		63		dB
Blocking and desensitization, 20 MHz from upper band edge	Wanted signal at -97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%		63		dB
Blocking and desensitization, 50 MHz from upper band edge	Wanted signal at -97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%		66		dB
Blocking and desensitization, -5 MHz from lower band edge	Wanted signal at -97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%		60		dB
Blocking and desensitization, -10 MHz from lower band edge	Wanted signal at -97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%		60		dB
Blocking and desensitization, -20 MHz from lower band edge	Wanted signal at -97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%		63		dB
Blocking and desensitization, -50 MHz from lower band edge	Wanted signal at -97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%		64		dB
Spurious emissions, 30 MHz to 1000 MHz	Measurement in a 50- Ω single-ended load		-66		dBm
Spurious emissions, 1 GHz to 12.75 GHz	Measurement in a 50- Ω single-ended load		-53		dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency		> 350		ppm
Symbol rate error tolerance	Difference between incoming symbol rate and the internally generated symbol rate		> 1000		ppm
RSSI dynamic range			95		dB
RSSI accuracy			± 4		dB

8.14 Timing and Switching Characteristics

8.14.1 Reset Timing

PARAMETER	MIN	TYP	MAX	UNIT
RESET_N low duration	1			μs

8.14.2 Wakeup Timing

Measured over operating free-air temperature with $V_{DD5} = 3.0\text{ V}$ (unless otherwise noted). The times listed here do not include software overhead.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
MCU, Reset to Active ⁽¹⁾		850	4300		μs
MCU, Shutdown to Active ⁽¹⁾		850	4300		μs

8.14.2 Wakeup Timing (continued)

Measured over operating free-air temperature with $V_{DD5} = 3.0\text{ V}$ (unless otherwise noted). The times listed here do not include software overhead.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
MCU, Standby to Active			160		μs
MCU, Active to Standby			36		μs
MCU, Idle to Active			14		μs

- (1) The wakeup time is dependent on remaining charge on VDDR capacitor when starting the device, and thus how long the device has been in Reset or Shutdown before starting up again.

8.14.3 Clock Specifications

8.14.3.1 48 MHz Bulk Acoustic Wave (BAW) Oscillator

Measured on CC26x2RBEM-7ID reference design with $T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$, unless otherwise noted.

	PARAMETER	MIN	TYP	MAX	UNIT
	Clock frequency ⁽¹⁾		48		MHz
	Compensated clock frequency for RF PLL and Modem ⁽²⁾	-40		40	ppm
	Start-up time ⁽³⁾		80		μs

- (1) Compensated clock frequency used by RF PLL and Modem. Non-RF domain (MCU and Peripherals) uncompensated frequency has variation upto +/- 0.4% in offset and +/- 200 ppm across temperature.
- (2) Across operational temperature range, including 10 year aging at 30°C. Compensation parameters are measured in TI production and stored in device for clock compensation.
- (3) Start-up time using the TI-provided power driver.

8.14.3.2 48 MHz Crystal Oscillator (XOSC_HF)

Measured on a Texas Instruments reference design with $T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$, unless otherwise noted.⁽¹⁾

	PARAMETER	MIN	TYP	MAX	UNIT
	Crystal frequency		48		MHz
ESR	Equivalent series resistance $6\text{ pF} < C_L \leq 9\text{ pF}$		20	60	Ω
ESR	Equivalent series resistance $5\text{ pF} < C_L \leq 6\text{ pF}$			80	Ω
L_M	Motional inductance, relates to the load capacitance that is used for the crystal (C_L in Farads) ⁽⁵⁾		$< 3 \times 10^{-25} / C_L^2$		H
C_L	Crystal load capacitance ⁽⁴⁾	5	7 ⁽³⁾	9	pF
	Start-up time ⁽²⁾		200		μs

- (1) Probing or otherwise stopping the crystal while the DC/DC converter is enabled may cause permanent damage to the device.
- (2) Start-up time using the TI-provided power driver. Start-up time may increase if driver is not used.
- (3) On-chip default connected capacitance including reference design parasitic capacitance. Connected internal capacitance is changed through software in the Customer Configuration section (CCFG).
- (4) Adjustable load capacitance is integrated into the device.
- (5) The crystal manufacturer's specification must satisfy this requirement for proper operation.

8.14.3.3 48 MHz RC Oscillator (RCOSC_HF)

Measured on a Texas Instruments reference design with $T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$, unless otherwise noted.

	MIN	TYP	MAX	UNIT
Frequency		48		MHz
Uncalibrated frequency accuracy		± 1		%
Calibrated frequency accuracy ⁽¹⁾		± 0.25		%
Start-up time		5		μs

- (1) Accuracy relative to the calibration source (XOSC_HF)

8.14.3.4 2 MHz RC Oscillator (RCOSC_MF)

Measured on a Texas Instruments reference design with $T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$, unless otherwise noted.

	MIN	TYP	MAX	UNIT
Calibrated frequency		2		MHz
Start-up time		5		μs

8.14.3.5 32.768 kHz Crystal Oscillator (XOSC_LF)

Measured on a Texas Instruments reference design with $T_c = 25\text{ }^\circ\text{C}$, $V_{\text{DDS}} = 3.0\text{ V}$, unless otherwise noted.

		MIN	TYP	MAX	UNIT
	Crystal frequency		32.768		kHz
ESR	Equivalent series resistance		30	100	k Ω
C_L	Crystal load capacitance	6	7 ⁽¹⁾	12	pF

- (1) Default load capacitance using TI reference designs including parasitic capacitance. Crystals with different load capacitance may be used.

8.14.3.6 32 kHz RC Oscillator (RCOSC_LF)

Measured on a Texas Instruments reference design with $T_c = 25\text{ }^\circ\text{C}$, $V_{\text{DDS}} = 3.0\text{ V}$, unless otherwise noted.

		MIN	TYP	MAX	UNIT
	Calibrated frequency		32.8 ⁽¹⁾		kHz
	Temperature coefficient.		50		ppm/ $^\circ\text{C}$

- (1) When using RCOSC_LF as source for the low frequency system clock (SCLK_LF), the accuracy of the SCLK_LF-derived Real Time Clock (RTC) can be improved by measuring RCOSC_LF relative to XOSC_HF and compensating for the RTC tick speed. This functionality is available through the TI-provided Power driver.

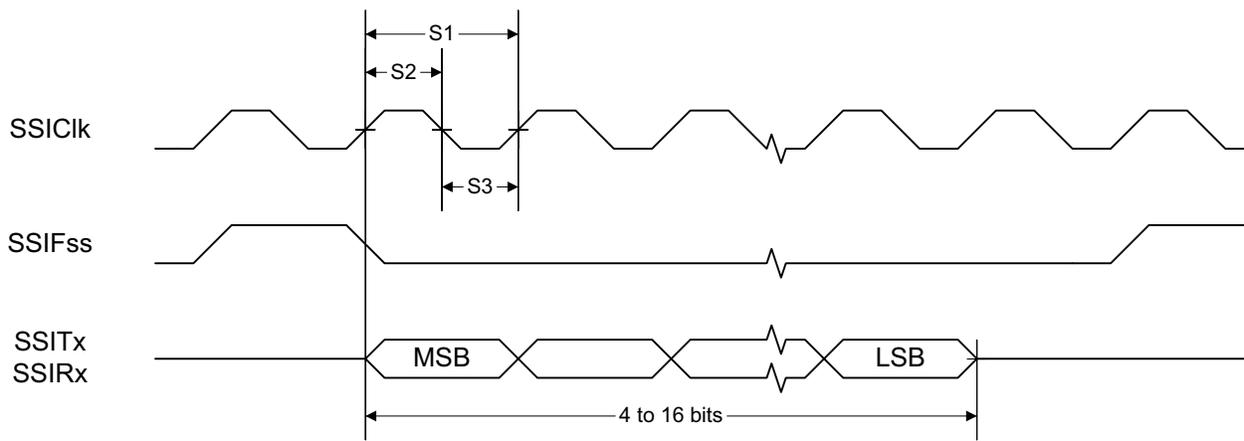
8.14.4 Synchronous Serial Interface (SSI) Characteristics

8.14.4.1 Synchronous Serial Interface (SSI) Characteristics

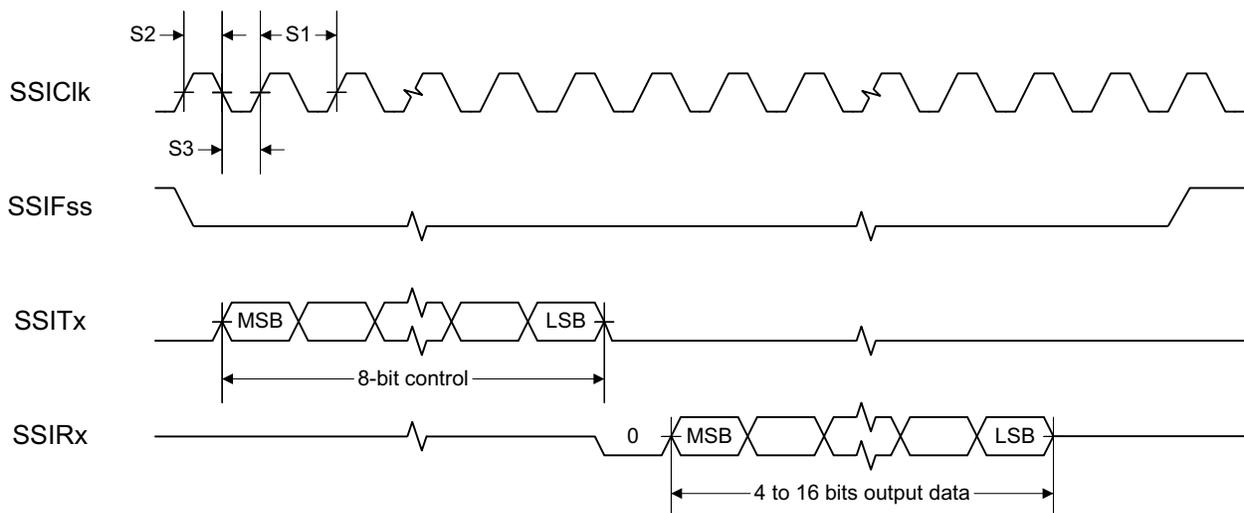
over operating free-air temperature range (unless otherwise noted)

PARAMETER NO.	PARAMETER		MIN	TYP	MAX	UNIT
S1	$t_{\text{clk_per}}$	SSIClk cycle time	12		65024	System Clocks ⁽²⁾
S2 ⁽¹⁾	$t_{\text{clk_high}}$	SSIClk high time		0.5		$t_{\text{clk_per}}$
S3 ⁽¹⁾	$t_{\text{clk_low}}$	SSIClk low time		0.5		$t_{\text{clk_per}}$

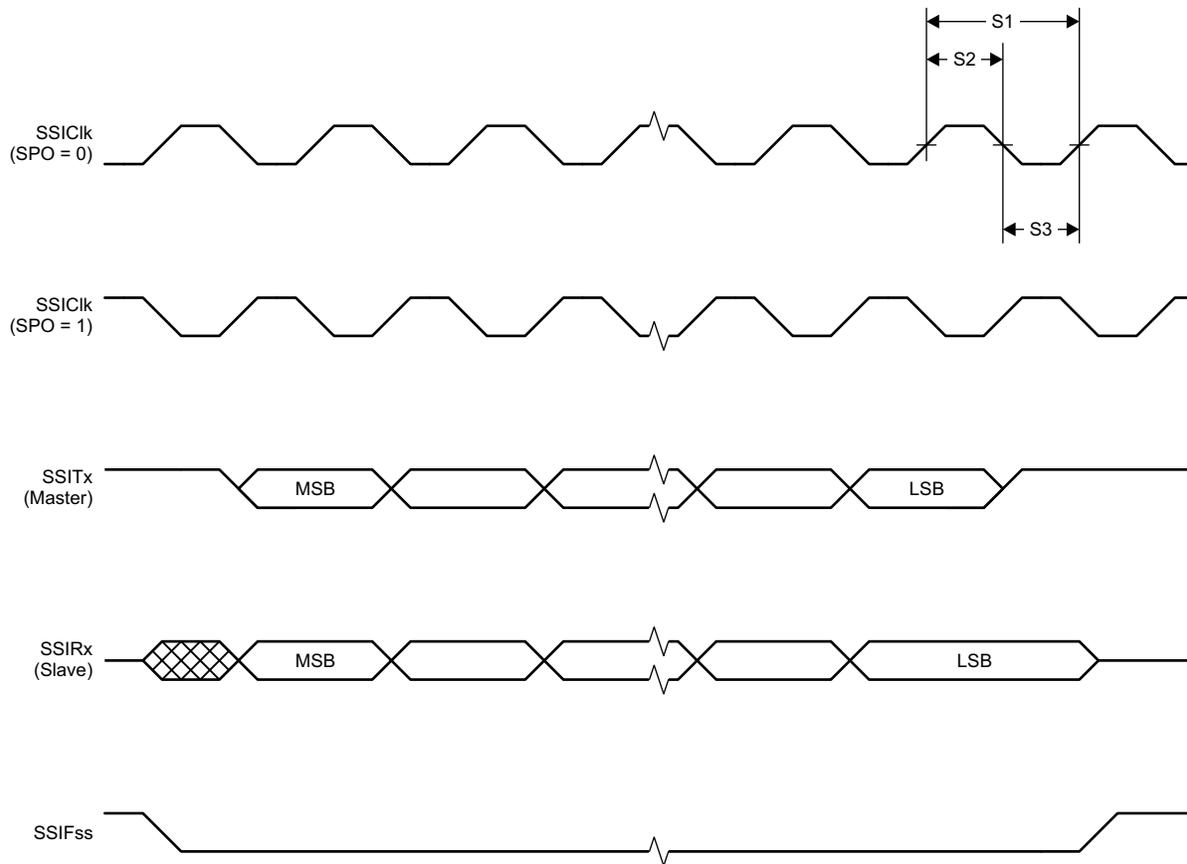
- (1) Refer to SSI timing diagrams [8-1](#), [8-2](#), and [8-3](#)
 (2) When using the TI-provided Power driver, the SSI system clock is always 48 MHz.



8-1. SSI Timing for TI Frame Format (FRF = 01), Single Transfer Timing Measurement



8-2. SSI Timing for MICROWIRE Frame Format (FRF = 10), Single Transfer



8-3. SSI Timing for SPI Frame Format (FRF = 00), With SPH = 1

8.14.5 UART

8.14.5.1 UART Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	MIN	TYP	MAX	UNIT
UART rate			3	MBaud

8.15 Peripheral Characteristics

8.15.1 ADC

8.15.1.1 Analog-to-Digital Converter (ADC) Characteristics

$T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$ and voltage scaling enabled, unless otherwise noted.⁽¹⁾

Performance numbers require use of offset and gain adjustments in software by TI-provided ADC drivers.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Input voltage range		0		VDDS	V
	Resolution			12		Bits
	Sample Rate				200	ksps
	Offset	Internal 4.3 V equivalent reference ⁽²⁾		-0.24		LSB
	Gain error	Internal 4.3 V equivalent reference ⁽²⁾		7.14		LSB
DNL ⁽⁴⁾	Differential nonlinearity			>-1		LSB
INL	Integral nonlinearity			±4		LSB
ENOB	Effective number of bits	Internal 4.3 V equivalent reference ⁽²⁾ , 200 kSamples/s, 9.6 kHz input tone		9.8		Bits
		Internal 4.3 V equivalent reference ⁽²⁾ , 200 kSamples/s, 9.6 kHz input tone, DC/DC enabled		9.8		
		VDDS as reference, 200 kSamples/s, 9.6 kHz input tone		10.1		
		Internal reference, voltage scaling disabled, 32 samples average, 200 kSamples/s, 300 Hz input tone		11.1		
		Internal reference, voltage scaling disabled, 14-bit mode, 200 kSamples/s, 600 Hz input tone ⁽⁵⁾		11.3		
		Internal reference, voltage scaling disabled, 15-bit mode, 200 kSamples/s, 150 Hz input tone ⁽⁵⁾		11.6		
THD	Total harmonic distortion	Internal 4.3 V equivalent reference ⁽²⁾ , 200 kSamples/s, 9.6 kHz input tone		-65		dB
		VDDS as reference, 200 kSamples/s, 9.6 kHz input tone		-70		
		Internal reference, voltage scaling disabled, 32 samples average, 200 kSamples/s, 300 Hz input tone		-72		
SINAD, SNDR	Signal-to-noise and distortion ratio	Internal 4.3 V equivalent reference ⁽²⁾ , 200 kSamples/s, 9.6 kHz input tone		60		dB
		VDDS as reference, 200 kSamples/s, 9.6 kHz input tone		63		
		Internal reference, voltage scaling disabled, 32 samples average, 200 kSamples/s, 300 Hz input tone		68		
SFDR	Spurious-free dynamic range	Internal 4.3 V equivalent reference ⁽²⁾ , 200 kSamples/s, 9.6 kHz input tone		70		dB
		VDDS as reference, 200 kSamples/s, 9.6 kHz input tone		73		
		Internal reference, voltage scaling disabled, 32 samples average, 200 kSamples/s, 300 Hz input tone		75		
	Conversion time	Serial conversion, time-to-output, 24 MHz clock		50		Clock Cycles
	Current consumption	Internal 4.3 V equivalent reference ⁽²⁾		0.42		mA
	Current consumption	VDDS as reference		0.6		mA

8.15.1.1 Analog-to-Digital Converter (ADC) Characteristics (continued)

$T_c = 25\text{ }^\circ\text{C}$, $V_{\text{DDS}} = 3.0\text{ V}$ and voltage scaling enabled, unless otherwise noted.⁽¹⁾

Performance numbers require use of offset and gain adjustments in software by TI-provided ADC drivers.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Reference voltage	Equivalent fixed internal reference (input voltage scaling enabled). For best accuracy, the ADC conversion should be initiated through the TI-RTOS API in order to include the gain/offset compensation factors stored in FCFG1		4.3 ^{(2) (3)}		V
	Reference voltage	Fixed internal reference (input voltage scaling disabled). For best accuracy, the ADC conversion should be initiated through the TI-RTOS API in order to include the gain/offset compensation factors stored in FCFG1. This value is derived from the scaled value (4.3 V) as follows: $V_{\text{ref}} = 4.3\text{ V} \times 1408 / 4095$		1.48		V
	Reference voltage	VDDS as reference, input voltage scaling enabled		VDDS		V
	Reference voltage	VDDS as reference, input voltage scaling disabled		VDDS / 2.82 ⁽³⁾		V
	Input impedance	200 kSamples/s, voltage scaling enabled. Capacitive input, Input impedance depends on sampling frequency and sampling time		>1		MΩ

- (1) Using IEEE Std 1241-2010 for terminology and test methods
- (2) Input signal scaled down internally before conversion, as if voltage range was 0 to 4.3 V
- (3) Applied voltage must be within Absolute Maximum Ratings (see [セクション 8.1](#)) at all times
- (4) No missing codes
- (5) $\text{ADC_output} = \Sigma(4^n \text{ samples}) \gg n$, n = desired extra bits

8.15.2 DAC

8.15.2.1 Digital-to-Analog Converter (DAC) Characteristics

$T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
General Parameters						
	Resolution			8		Bits
V_{DD5}	Supply voltage	Any load, any V_{REF} , pre-charge OFF, DAC charge-pump ON	1.8		3.8	V
		External Load ⁽⁴⁾ , any V_{REF} , pre-charge OFF, DAC charge-pump OFF	2.0		3.8	
		Any load, $V_{REF} = \text{DCOUP}$ L, pre-charge ON	2.6		3.8	
F_{DAC}	Clock frequency	Buffer ON (recommended for external load)	16		250	kHz
		Buffer OFF (internal load)	16		1000	
	Voltage output settling time	$V_{REF} = V_{DD5}$, buffer OFF, internal load		13		1 / F_{DAC}
		$V_{REF} = V_{DD5}$, buffer ON, external capacitive load = 20 pF ⁽³⁾		13.8		
	External capacitive load			20	200	pF
	External resistive load		10			MΩ
	Short circuit current				400	μA
Z_{MAX}	Max output impedance $V_{ref} = V_{DD5}$, buffer ON, CLK 250 kHz	$V_{DD5} = 3.8\text{ V}$, DAC charge-pump OFF		50.8		kΩ
		$V_{DD5} = 3.0\text{ V}$, DAC charge-pump ON		51.7		
		$V_{DD5} = 3.0\text{ V}$, DAC charge-pump OFF		53.2		
		$V_{DD5} = 2.0\text{ V}$, DAC charge-pump ON		48.7		
		$V_{DD5} = 2.0\text{ V}$, DAC charge-pump OFF		70.2		
		$V_{DD5} = 1.8\text{ V}$, DAC charge-pump ON		46.3		
		$V_{DD5} = 1.8\text{ V}$, DAC charge-pump OFF		88.9		
Internal Load - Continuous Time Comparator / Low Power Clocked Comparator						
DNL	Differential nonlinearity	$V_{REF} = V_{DD5}$, load = Continuous Time Comparator or Low Power Clocked Comparator $F_{DAC} = 250\text{ kHz}$		±1		LSB ⁽¹⁾
	Differential nonlinearity	$V_{REF} = V_{DD5}$, load = Continuous Time Comparator or Low Power Clocked Comparator $F_{DAC} = 16\text{ kHz}$		±1.2		
	Offset error ⁽²⁾ Load = Continuous Time Comparator	$V_{REF} = V_{DD5} = 3.8\text{ V}$		±0.64		LSB ⁽¹⁾
		$V_{REF} = V_{DD5} = 3.0\text{ V}$		±0.81		
		$V_{REF} = V_{DD5} = 1.8\text{ V}$		±1.27		
		$V_{REF} = \text{DCOUP}$ L, pre-charge ON		±3.43		
		$V_{REF} = \text{DCOUP}$ L, pre-charge OFF		±2.88		
		$V_{REF} = \text{ADCRE}$ F		±2.37		
	Offset error ⁽²⁾ Load = Low Power Clocked Comparator	$V_{REF} = V_{DD5} = 3.8\text{ V}$		±0.78		LSB ⁽¹⁾
		$V_{REF} = V_{DD5} = 3.0\text{ V}$		±0.77		
		$V_{REF} = V_{DD5} = 1.8\text{ V}$		±3.46		
		$V_{REF} = \text{DCOUP}$ L, pre-charge ON		±3.44		
		$V_{REF} = \text{DCOUP}$ L, pre-charge OFF		±4.70		
		$V_{REF} = \text{ADCRE}$ F		±4.11		

8.15.2.1 Digital-to-Analog Converter (DAC) Characteristics (continued)

$T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Max code output voltage variation ⁽²⁾ Load = Continuous Time Comparator		$V_{REF} = V_{DD5} = 3.8\text{ V}$		±1.53		LSB ⁽¹⁾
		$V_{REF} = V_{DD5} = 3.0\text{ V}$		±1.71		
		$V_{REF} = V_{DD5} = 1.8\text{ V}$		±2.10		
		$V_{REF} = \text{DCOUPPL}$, pre-charge ON		±6.00		
		$V_{REF} = \text{DCOUPPL}$, pre-charge OFF		±3.85		
		$V_{REF} = \text{ADCREFL}$		±5.84		
Max code output voltage variation ⁽²⁾ Load = Low Power Clocked Comparator		$V_{REF} = V_{DD5} = 3.8\text{ V}$		±2.92		LSB ⁽¹⁾
		$V_{REF} = V_{DD5} = 3.0\text{ V}$		±3.06		
		$V_{REF} = V_{DD5} = 1.8\text{ V}$		±3.91		
		$V_{REF} = \text{DCOUPPL}$, pre-charge ON		±7.84		
		$V_{REF} = \text{DCOUPPL}$, pre-charge OFF		±4.06		
		$V_{REF} = \text{ADCREFL}$		±6.94		
Output voltage range ⁽²⁾ Load = Continuous Time Comparator		$V_{REF} = V_{DD5} = 3.8\text{ V}$, code 1		0.03		V
		$V_{REF} = V_{DD5} = 3.8\text{ V}$, code 255		3.62		
		$V_{REF} = V_{DD5} = 3.0\text{ V}$, code 1		0.02		
		$V_{REF} = V_{DD5} = 3.0\text{ V}$, code 255		2.86		
		$V_{REF} = V_{DD5} = 1.8\text{ V}$, code 1		0.01		
		$V_{REF} = V_{DD5} = 1.8\text{ V}$, code 255		1.71		
		$V_{REF} = \text{DCOUPPL}$, pre-charge OFF, code 1		0.01		
		$V_{REF} = \text{DCOUPPL}$, pre-charge OFF, code 255		1.21		
		$V_{REF} = \text{DCOUPPL}$, pre-charge ON, code 1		1.27		
		$V_{REF} = \text{DCOUPPL}$, pre-charge ON, code 255		2.46		
		$V_{REF} = \text{ADCREFL}$, code 1		0.01		
		$V_{REF} = \text{ADCREFL}$, code 255		1.41		
Output voltage range ⁽²⁾ Load = Low Power Clocked Comparator		$V_{REF} = V_{DD5} = 3.8\text{ V}$, code 1		0.03		V
		$V_{REF} = V_{DD5} = 3.8\text{ V}$, code 255		3.61		
		$V_{REF} = V_{DD5} = 3.0\text{ V}$, code 1		0.02		
		$V_{REF} = V_{DD5} = 3.0\text{ V}$, code 255		2.85		
		$V_{REF} = V_{DD5} = 1.8\text{ V}$, code 1		0.01		
		$V_{REF} = V_{DD5} = 1.8\text{ V}$, code 255		1.71		
		$V_{REF} = \text{DCOUPPL}$, pre-charge OFF, code 1		0.01		
		$V_{REF} = \text{DCOUPPL}$, pre-charge OFF, code 255		1.21		
		$V_{REF} = \text{DCOUPPL}$, pre-charge ON, code 1		1.27		
		$V_{REF} = \text{DCOUPPL}$, pre-charge ON, code 255		2.46		
		$V_{REF} = \text{ADCREFL}$, code 1		0.01		
		$V_{REF} = \text{ADCREFL}$, code 255		1.41		
External Load (Keysight 34401A Multimeter)						
INL	Integral nonlinearity	$V_{REF} = V_{DD5}$, $F_{DAC} = 250\text{ kHz}$		±1		LSB ⁽¹⁾
		$V_{REF} = \text{DCOUPPL}$, $F_{DAC} = 250\text{ kHz}$		±1		
		$V_{REF} = \text{ADCREFL}$, $F_{DAC} = 250\text{ kHz}$		±1		
DNL	Differential nonlinearity	$V_{REF} = V_{DD5}$, $F_{DAC} = 250\text{ kHz}$		±1		LSB ⁽¹⁾

8.15.2.1 Digital-to-Analog Converter (DAC) Characteristics (continued)

T_c = 25 °C, V_{DDS} = 3.0 V, unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Offset error	V _{REF} = V _{DDS} = 3.8 V		±0.20		LSB ⁽¹⁾
	V _{REF} = V _{DDS} = 3.0 V		±0.25		
	V _{REF} = V _{DDS} = 1.8 V		±0.45		
	V _{REF} = DCOUPL, pre-charge ON		±1.55		
	V _{REF} = DCOUPL, pre-charge OFF		±1.30		
	V _{REF} = ADCREF		±1.10		
Max code output voltage variation	V _{REF} = V _{DDS} = 3.8 V		±0.60		LSB ⁽¹⁾
	V _{REF} = V _{DDS} = 3.0 V		±0.55		
	V _{REF} = V _{DDS} = 1.8 V		±0.60		
	V _{REF} = DCOUPL, pre-charge ON		±3.45		
	V _{REF} = DCOUPL, pre-charge OFF		±2.10		
	V _{REF} = ADCREF		±1.90		
Output voltage range Load = Low Power Clocked Comparator	V _{REF} = V _{DDS} = 3.8 V, code 1		0.03		V
	V _{REF} = V _{DDS} = 3.8 V, code 255		3.61		
	V _{REF} = V _{DDS} = 3.0 V, code 1		0.02		
	V _{REF} = V _{DDS} = 3.0 V, code 255		2.85		
	V _{REF} = V _{DDS} = 1.8 V, code 1		0.02		
	V _{REF} = V _{DDS} = 1.8 V, code 255		1.71		
	V _{REF} = DCOUPL, pre-charge OFF, code 1		0.02		
	V _{REF} = DCOUPL, pre-charge OFF, code 255		1.20		
	V _{REF} = DCOUPL, pre-charge ON, code 1		1.27		
	V _{REF} = DCOUPL, pre-charge ON, code 255		2.46		
	V _{REF} = ADCREF, code 1		0.02		
	V _{REF} = ADCREF, code 255		1.42		

- (1) 1 LSB (V_{REF} 3.8 V/3.0 V/1.8 V/DCOUP/ADCREF) = 14.10 mV/11.13 mV/6.68 mV/4.67 mV/5.48 mV
- (2) Includes comparator offset
- (3) A load > 20 pF will increase the settling time
- (4) Keysight 34401A Multimeter

8.15.3 Temperature and Battery Monitor

8.15.3.1 Temperature Sensor

Measured on a Texas Instruments reference design with $T_c = 25\text{ }^\circ\text{C}$, $V_{\text{DDS}} = 3.0\text{ V}$, unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Resolution			2		$^\circ\text{C}$
Accuracy	$-40\text{ }^\circ\text{C}$ to $0\text{ }^\circ\text{C}$		± 4.0		$^\circ\text{C}$
Accuracy	$0\text{ }^\circ\text{C}$ to $105\text{ }^\circ\text{C}$		± 2.5		$^\circ\text{C}$
Supply voltage coefficient ⁽¹⁾			3.6		$^\circ\text{C}/\text{V}$

(1) The temperature sensor is automatically compensated for V_{DDS} variation when using the TI-provided driver.

8.15.3.2 Battery Monitor

Measured on a Texas Instruments reference design with $T_c = 25\text{ }^\circ\text{C}$, unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Resolution			25		mV
Range		1.8		3.8	V
Integral nonlinearity (max)			23		mV
Accuracy	$V_{\text{DDS}} = 3.0\text{ V}$		22.5		mV
Offset error			-32		mV
Gain error			-1		%

8.15.4 Comparators

8.15.4.1 Low-Power Clocked Comparator

$T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$, unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input voltage range		0		V_{DD5}	V
Clock frequency			SCLK_LF		
Internal reference voltage ⁽¹⁾	Using internal DAC with V_{DD5} as reference voltage, DAC code = 0 - 255		0.024 - 2.865		V
Offset	Measured at $V_{DD5} / 2$, includes error from internal DAC		± 5		mV
Decision time	Step from -50 mV to 50 mV		1		Clock Cycle

- (1) The comparator can use an internal 8 bits DAC as its reference. The DAC output voltage range depends on the reference voltage selected. See [セクション 8.15.2.1](#)

8.15.4.2 Continuous Time Comparator

$T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$, unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input voltage range ⁽¹⁾		0		V_{DD5}	V
Offset	Measured at $V_{DD5} / 2$		± 5		mV
Decision time	Step from -10 mV to 10 mV		0.78		μs
Current consumption	Internal reference		8.6		μA

- (1) The input voltages can be generated externally and connected throughout I/Os or an internal reference voltage can be generated using the DAC

8.15.5 Current Source

8.15.5.1 Programmable Current Source

$T_c = 25\text{ }^\circ\text{C}$, $V_{DD5} = 3.0\text{ V}$, unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Current source programmable output range (logarithmic range)			0.25 - 20		μA
Resolution			0.25		μA

8.15.6 GPIO

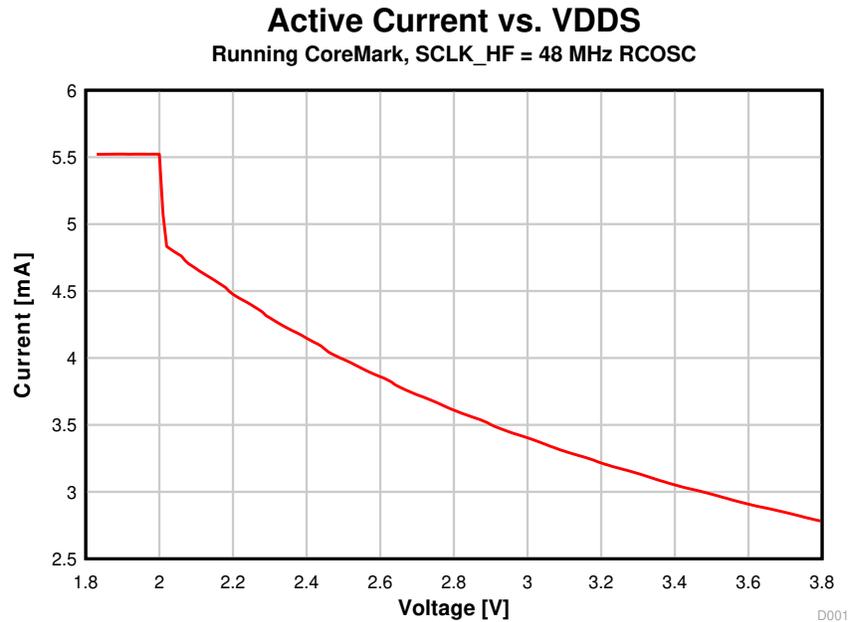
8.15.6.1 GPIO DC Characteristics

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
T_A = 25 °C, V_{DD5} = 1.8 V					
GPIO VOH at 8 mA load	IOCURR = 2, high-drive GPIOs only		1.56		V
GPIO VOL at 8 mA load	IOCURR = 2, high-drive GPIOs only		0.24		V
GPIO VOH at 4 mA load	IOCURR = 1		1.59		V
GPIO VOL at 4 mA load	IOCURR = 1		0.21		V
GPIO pullup current	Input mode, pullup enabled, Vpad = 0 V		73		μA
GPIO pulldown current	Input mode, pulldown enabled, Vpad = VDD5		19		μA
GPIO low-to-high input transition, with hysteresis	IH = 1, transition voltage for input read as 0 → 1		1.08		V
GPIO high-to-low input transition, with hysteresis	IH = 1, transition voltage for input read as 1 → 0		0.73		V
GPIO input hysteresis	IH = 1, difference between 0 → 1 and 1 → 0 points		0.35		V
T_A = 25 °C, V_{DD5} = 3.0 V					
GPIO VOH at 8 mA load	IOCURR = 2, high-drive GPIOs only		2.59		V
GPIO VOL at 8 mA load	IOCURR = 2, high-drive GPIOs only		0.42		V
GPIO VOH at 4 mA load	IOCURR = 1		2.63		V
GPIO VOL at 4 mA load	IOCURR = 1		0.40		V
T_A = 25 °C, V_{DD5} = 3.8 V					
GPIO pullup current	Input mode, pullup enabled, Vpad = 0 V		282		μA
GPIO pulldown current	Input mode, pulldown enabled, Vpad = VDD5		110		μA
GPIO low-to-high input transition, with hysteresis	IH = 1, transition voltage for input read as 0 → 1		1.97		V
GPIO high-to-low input transition, with hysteresis	IH = 1, transition voltage for input read as 1 → 0		1.55		V
GPIO input hysteresis	IH = 1, difference between 0 → 1 and 1 → 0 points		0.42		V
T_A = 25 °C					
VIH	Lowest GPIO input voltage reliably interpreted as a <i>High</i>	0.8*V _{DD5}			V
VIL	Highest GPIO input voltage reliably interpreted as a <i>Low</i>		0.2*V _{DD5}		V

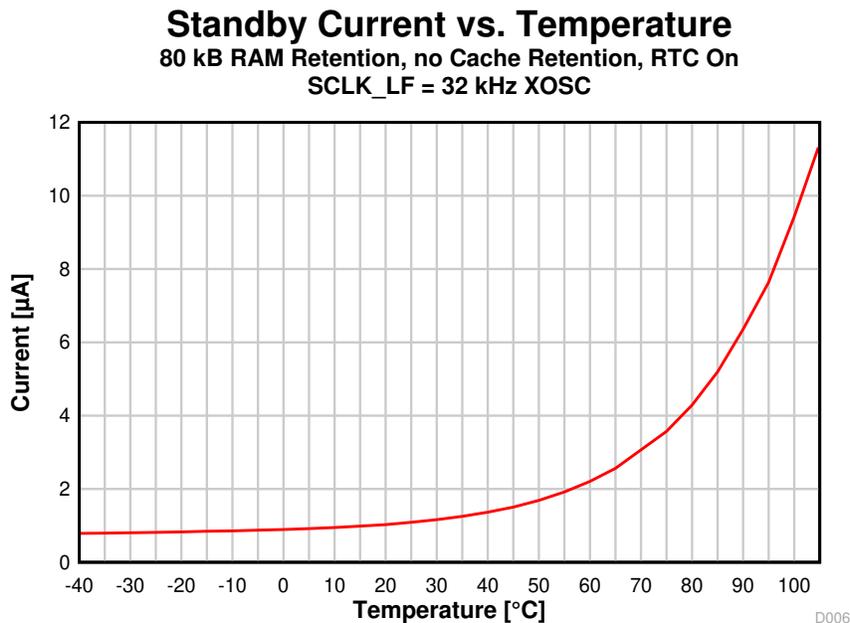
8.16 Typical Characteristics

All measurements in this section are done with $T_c = 25\text{ }^\circ\text{C}$ and $V_{DD5} = 3.0\text{ V}$, unless otherwise noted. See *Recommended Operating Conditions*, [セクション 8.3](#), for device limits. Values exceeding these limits are for reference only.

8.16.1 MCU Current



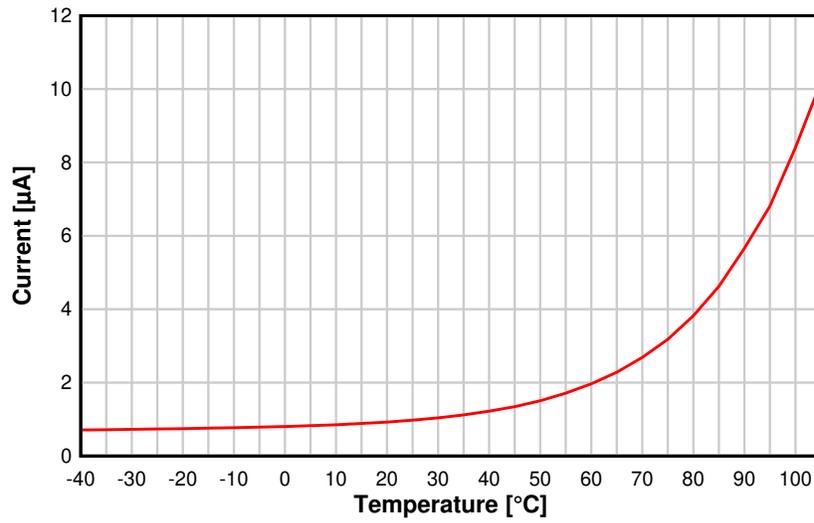
8-4. Active Mode (MCU) Current vs. Supply Voltage (VDD5)



8-5. Standby Mode (MCU) Current vs. Temperature

Standby Current vs. Temperature

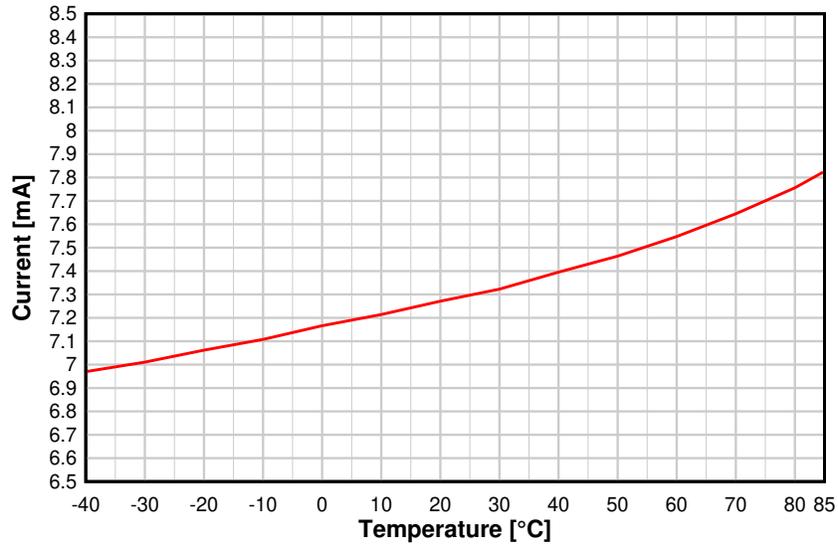
80 kB RAM Retention, no Cache Retention, RTC On
SCLK_LF = 32 kHz XOSC VDD5 = 3.6 V



8-6. Standby Mode (MCU) Current vs. Temperature (VDD5 = 3.6 V)

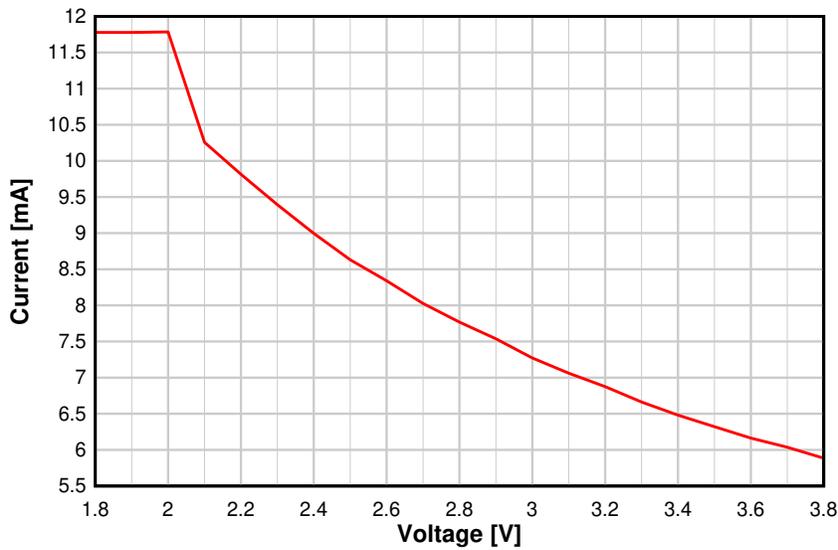
8.16.2 RX Current

RX Current vs. Temperature
 BLE 1 Mbps, 2.44 GHz



 **8-7. RX Current vs. Temperature (BLE 1 Mbps, 2.44 GHz)**

RX Current vs. VDD5
 BLE 1 Mbps, 2.44 GHz

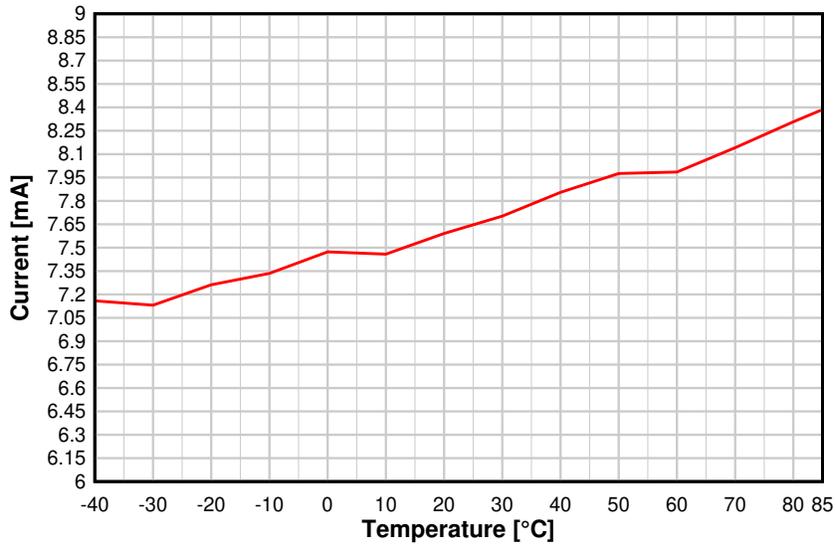


 **8-8. RX Current vs. Supply Voltage (VDD5) (BLE 1 Mbps, 2.44 GHz)**

8.16.3 TX Current

TX Current vs. Temperature

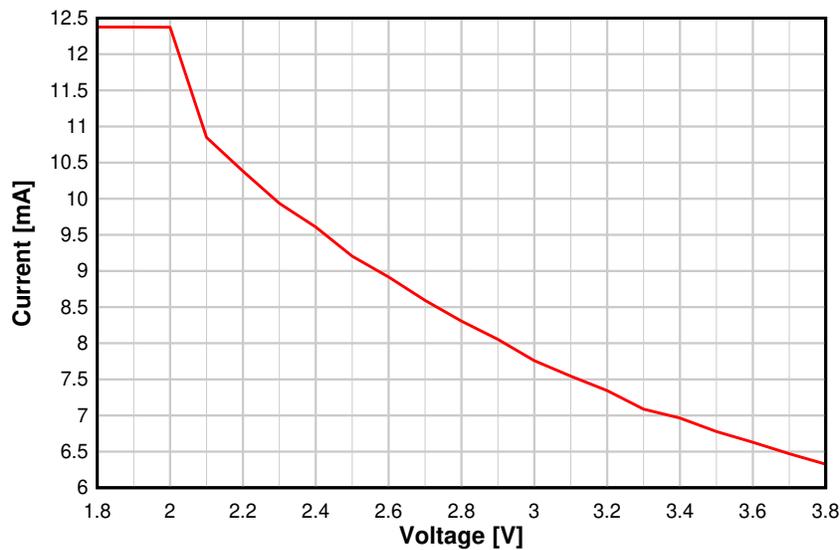
BLE 1 Mbps, 2.44 GHz, 0 dBm



8-9. TX Current vs. Temperature (BLE 1 Mbps, 2.44 GHz)

TX Current vs. VDD5

BLE 1 Mbps, 2.44 GHz, 0 dBm



8-10. TX Current vs. Supply Voltage (VDD5) (BLE 1 Mbps, 2.44 GHz)

表 8-1 shows typical TX current and output power for different output power settings.

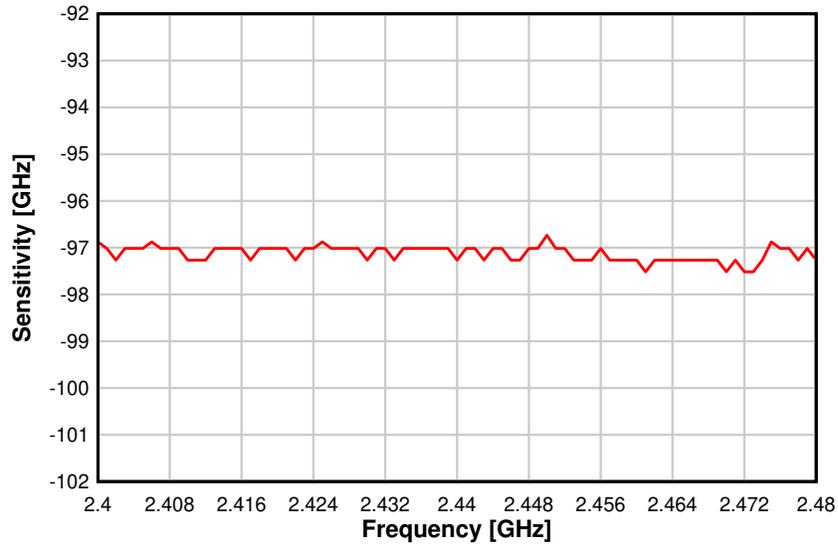
表 8-1. Typical TX Current and Output Power

CC2652RB at 2.44 GHz, VDDS = 3.0 V (Measured on CC26x2RBEM-7ID)			
txPower	TX Power Setting (SmartRF Studio)	Typical Output Power [dBm]	Typical Current Consumption [mA]
0x7217	5	5.3	10.1
0x4E63	4	4.2	9.5
0x385D	3	3.1	9
0x3259	2	2.1	8.5
0x2856	1	1.2	8.2
0x2853	0	0.1	7.8
0x12D6	-5	-5.0	6.7
0x0ACF	-10	-9.6	6.1
0x06CA	-15	-14.8	5.6
0x04C6	-21	-21.2	5.3

8.16.4 RX Performance

Sensitivity vs. Frequency

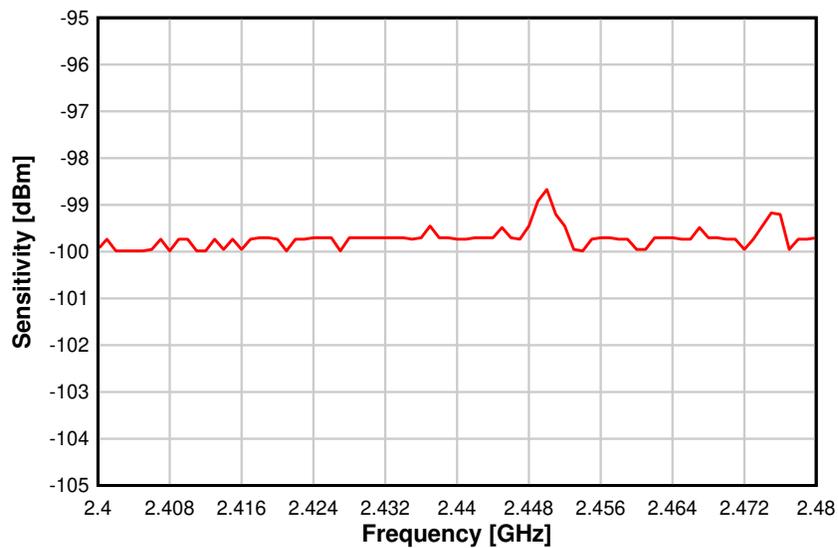
BLE 1 Mbps



8-11. Sensitivity vs. Frequency (BLE 1 Mbps, 2.44 GHz)

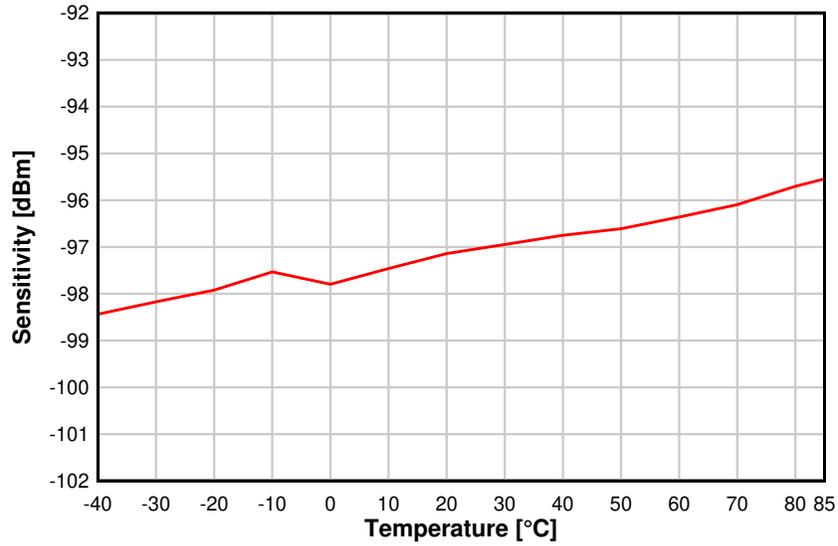
Sensitivity vs. Frequency

IEEE 802.15.4 (OQPSK DSSS1:8, 250 kbps)



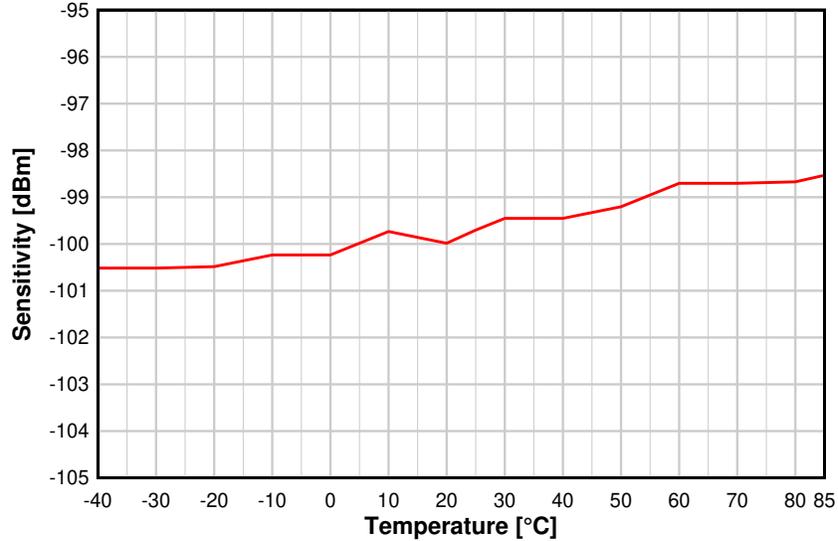
8-12. Sensitivity vs. Frequency IEEE 802.15.4 (OQPSK DSSS1:8, 250 kbps)

Sensitivity vs. Temperature BLE 1 Mbps, 2.44 GHz



8-13. Sensitivity vs. Temperature (BLE 1 Mbps, 2.44 GHz)

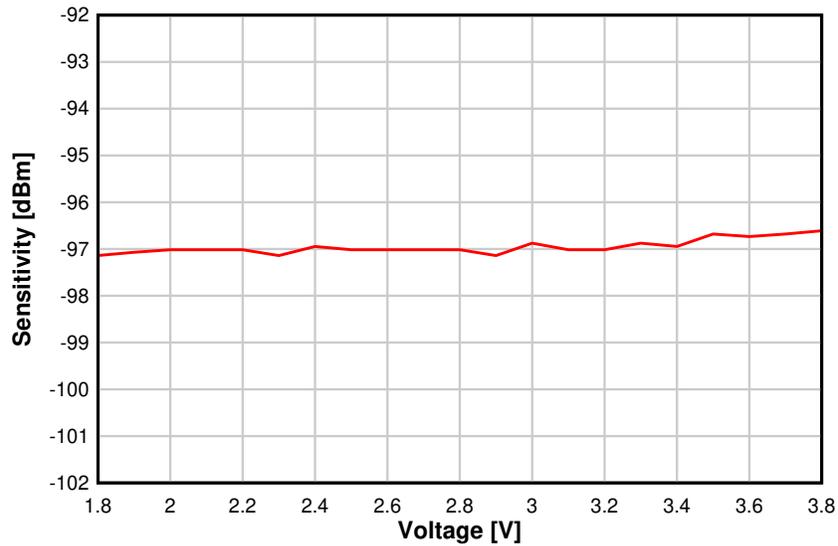
Sensitivity vs. Temperature IEEE 802.15.4 (OQPSK DSSS1:8, 250 kbps), 2.44 GHz



8-14. Sensitivity vs. Temperature IEEE 802.15.4 (OQPSK DSSS1:8, 250 kbps)

Sensitivity vs. VDD5

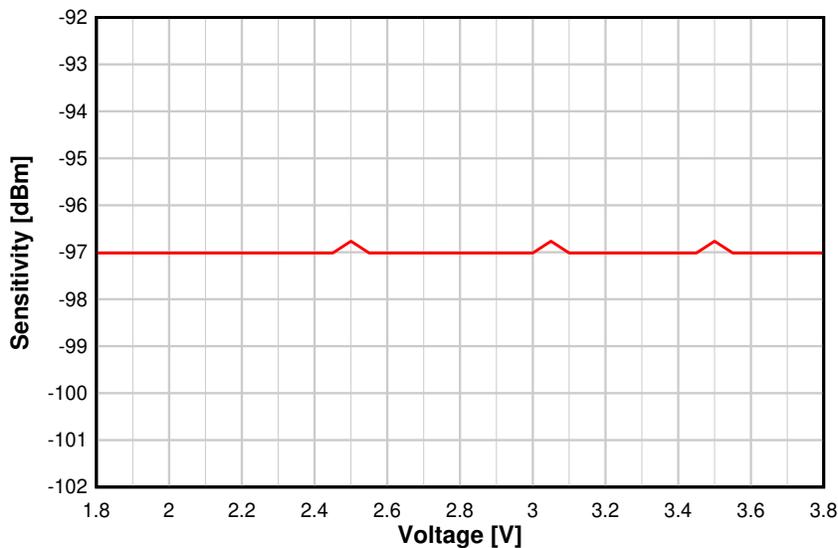
BLE 1 Mbps, 2.44 GHz



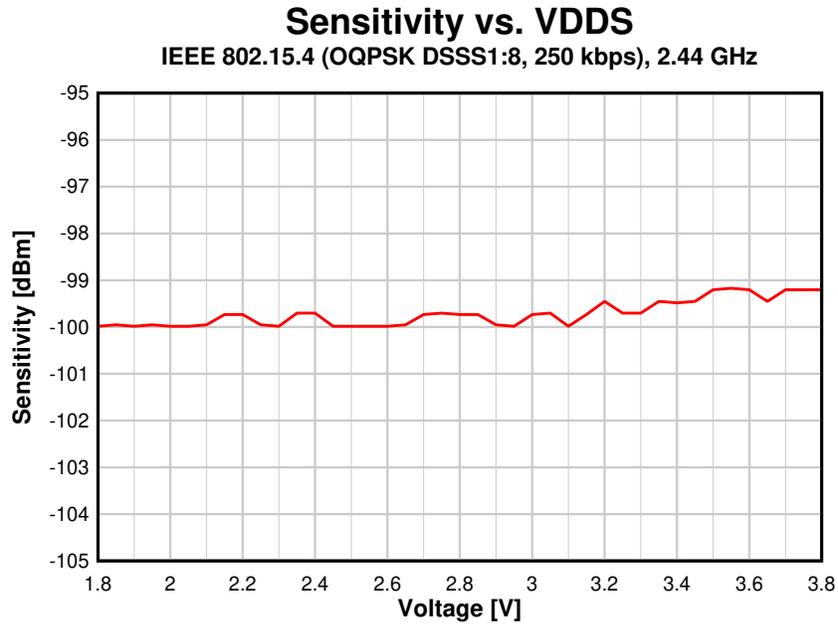
8-15. Sensitivity vs. Supply Voltage (VDD5) (BLE 1 Mbps, 2.44 GHz)

Sensitivity vs. VDD5

BLE 1 Mbps, 2.44 GHz, DCDC Off



8-16. Sensitivity vs. Supply Voltage (VDD5) (BLE 1 Mbps, 2.44 GHz, DCDC Off)

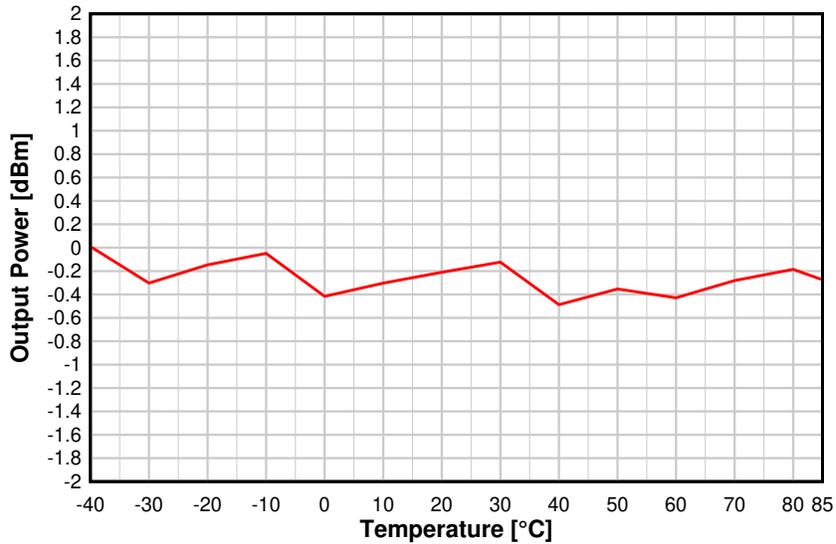


8-17. Sensitivity vs. Supply Voltage (VDDS) IEEE 802.15.4 (OQPSK DSSS1:8, 250 kbps)

8.16.5 TX Performance

Output Power vs. Temperature

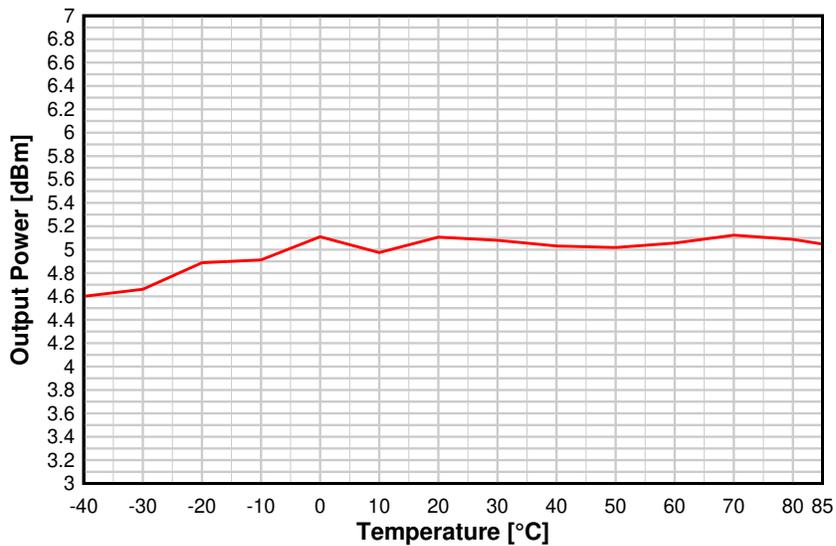
BLE 1 Mbps, 2.44 GHz, 0 dBm



8-18. Output Power vs. Temperature (BLE 1 Mbps, 2.44 GHz, 0 dBm)

Output Power vs. Temperature

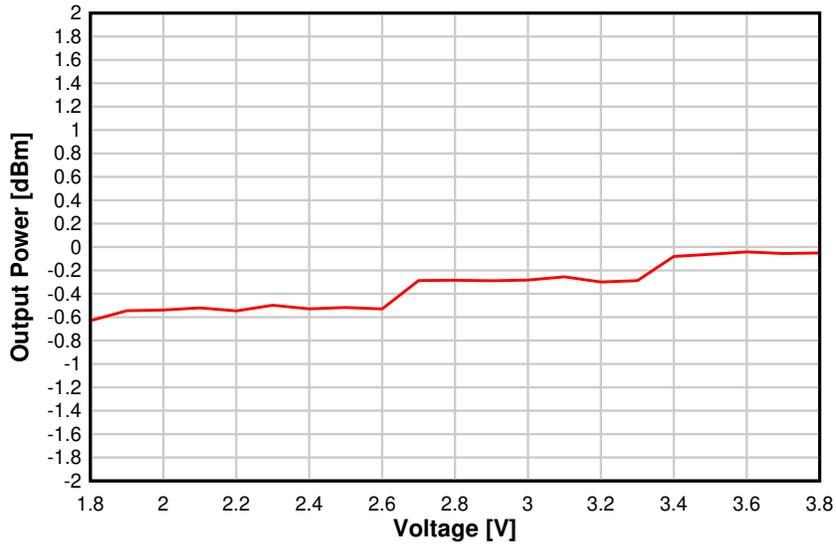
BLE 1 Mbps, 2.44 GHz, +5 dBm



8-19. Output Power vs. Temperature (BLE 1 Mbps, 2.44 GHz, +5 dBm)

Output Power vs. VDD5

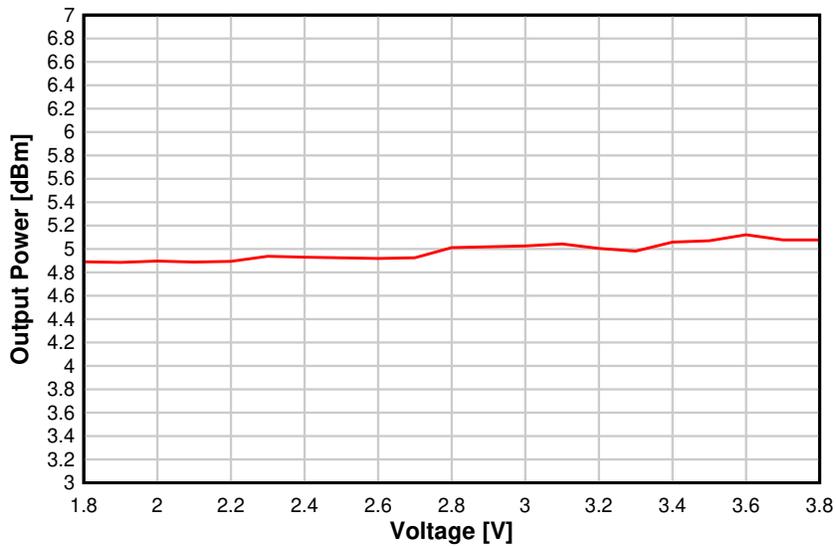
BLE 1 Mbps, 2.44 GHz, 0 dBm



 **8-20. Output Power vs. Supply Voltage (VDD5) (BLE 1 Mbps, 2.44 GHz, 0 dBm)**

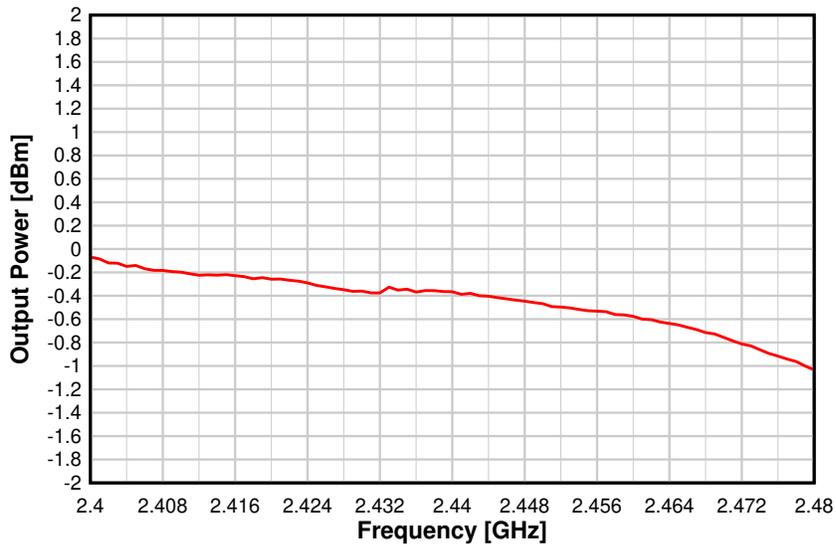
Output power vs. VDD5

BLE 1 Mbps, 2.44 GHz, +5 dBm



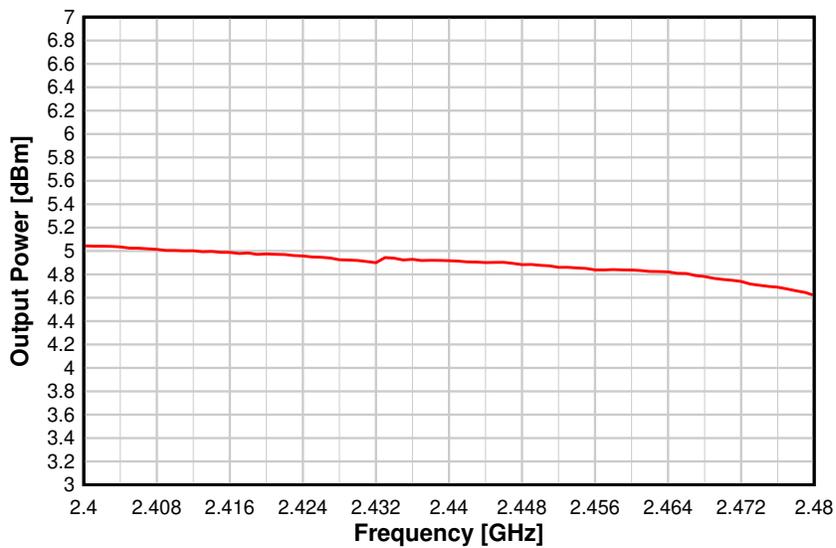
 **8-21. Output Power vs. Supply Voltage (VDD5) (BLE 1 Mbps, 2.44 GHz, +5 dBm)**

Output Power vs. Frequency BLE 1 Mbps, 2.44 GHz, 0 dBm



8-22. Output Power vs. Frequency (BLE 1 Mbps, 2.44 GHz, 0 dBm)

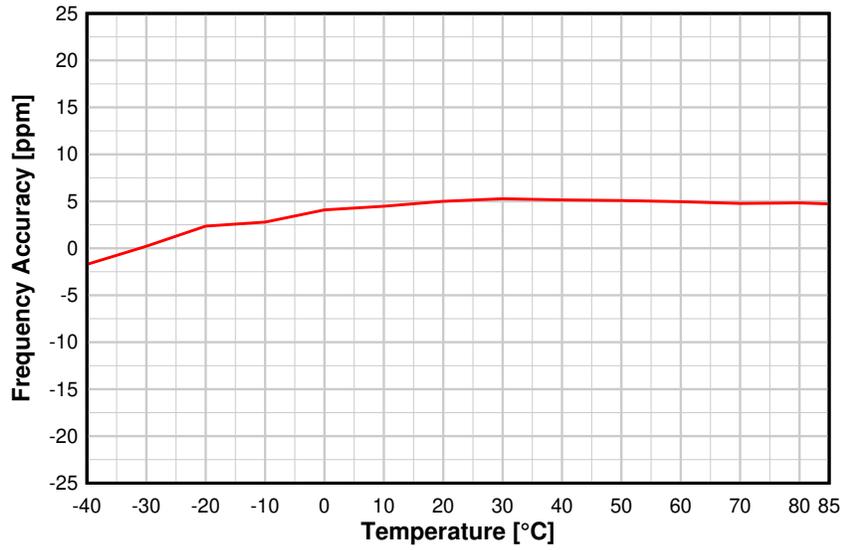
Output Power vs. Frequency BLE 1 Mbps, 2.44 GHz, +5 dBm



8-23. Output Power vs. Frequency (BLE 1 Mbps, 2.44 GHz, +5 dBm)

Compensated Frequency Accuracy vs. Temperature

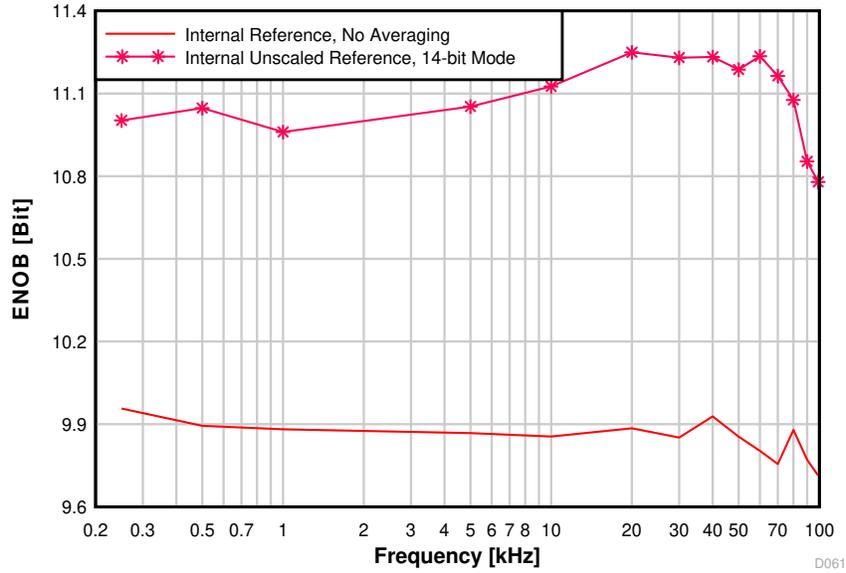
RF Frequency, 2.44 GHz



8-24. Compensated Frequency Accuracy vs. Temperature (2.44 GHz)

8.16.6 ADC Performance

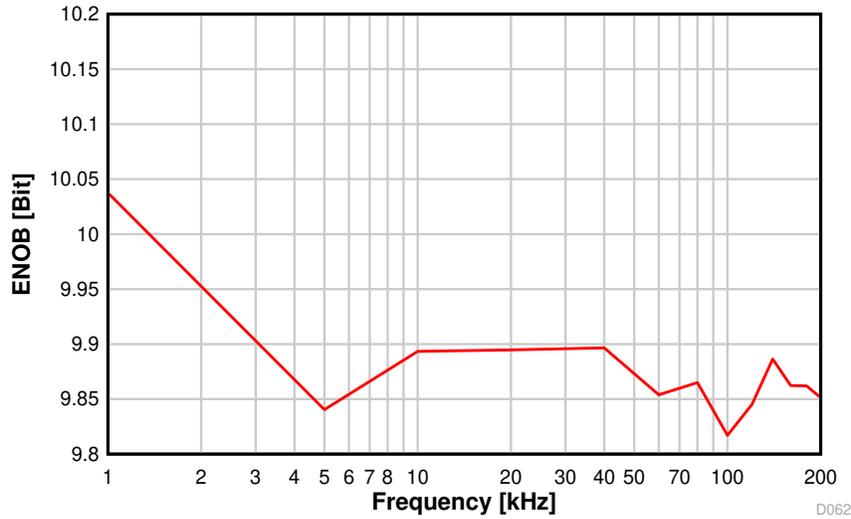
ENOB vs. Input Frequency



8-25. ENOB vs. Input Frequency

ENOB vs. Sampling Frequency

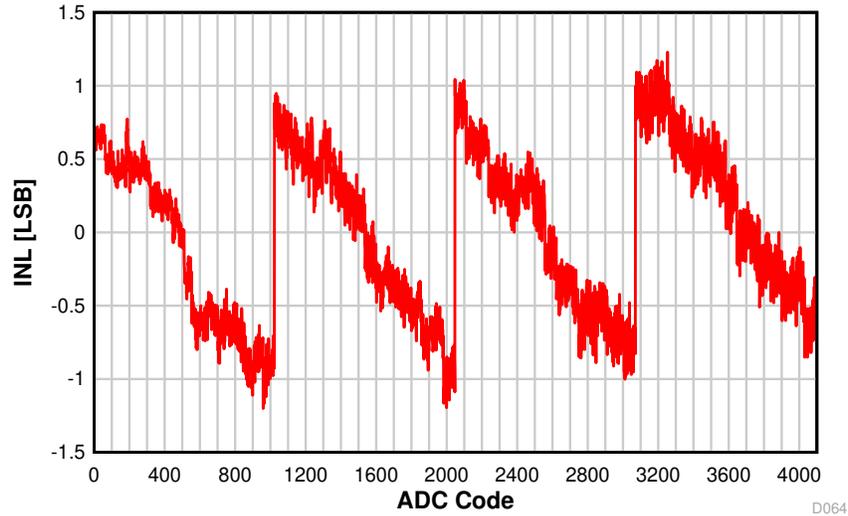
Vin = 3.0 V Sine wave, Internal reference,
Fin = Fs / 10



8-26. ENOB vs. Sampling Frequency

INL vs. ADC Code

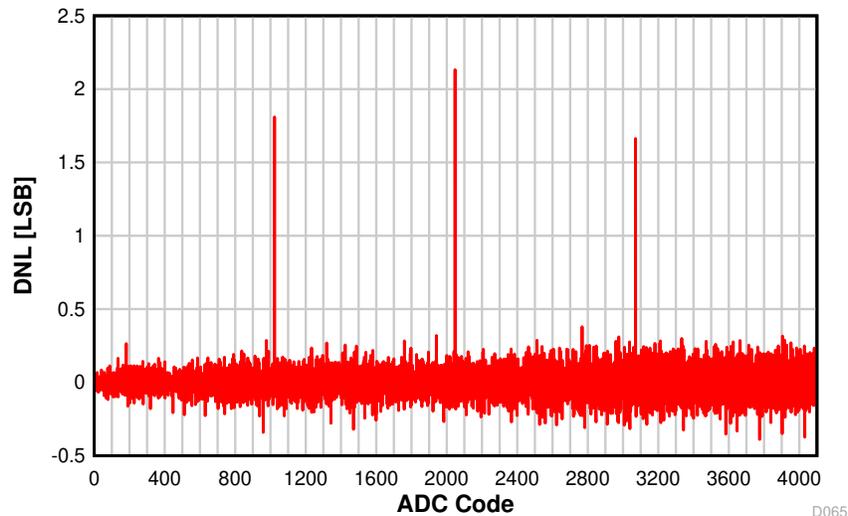
Vin = 3.0 V Sine wave, Internal reference,
200 kSamples/s



8-27. INL vs.
ADC Code

DNL vs. ADC Code

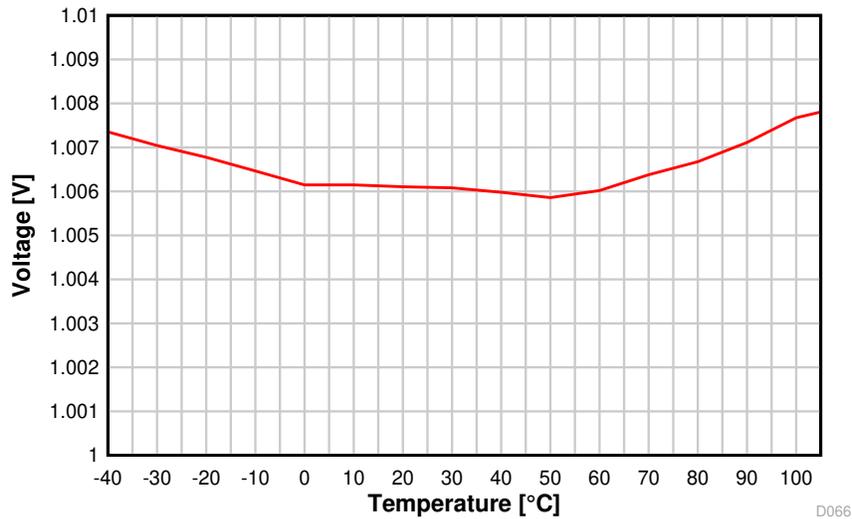
Vin = 3.0 V Sine wave, Internal reference,
200 kSamples/s



8-28. DNL vs.
ADC Code

ADC Accuracy vs. Temperature

Vin = 1 V, Internal reference,
200 kSamples/s

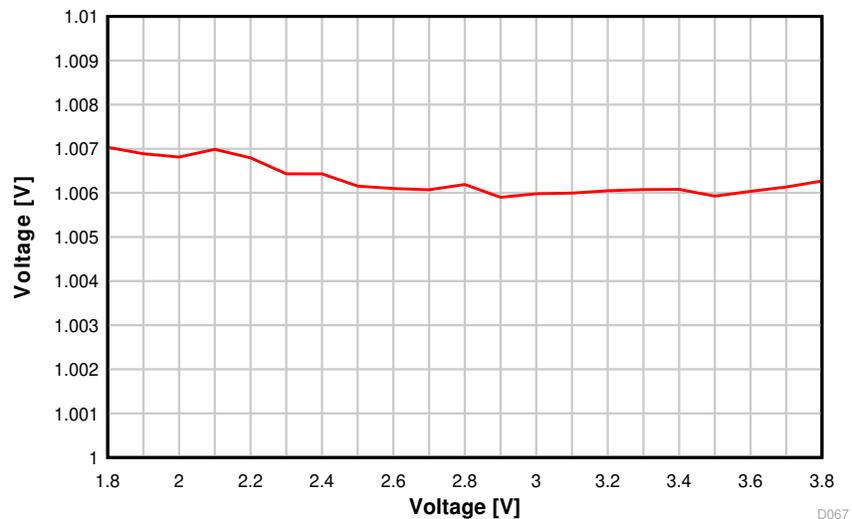


D066

8-29. ADC Accuracy vs. Temperature

ADC Accuracy vs. VDDS

Vin = 1 V, Internal reference,
200 kSamples/s



D067

8-30. ADC Accuracy vs. Supply Voltage (VDDS)

9 Detailed Description

9.1 Overview

セクション 4 shows the core modules of the CC2652RB device.

9.2 System CPU

The CC2652RB SimpleLink™ Wireless MCU contains an Arm® Cortex®-M4F system CPU, which runs the application and the higher layers of radio protocol stacks.

The system CPU is the foundation of a high-performance, low-cost platform that meets the system requirements of minimal memory implementation, and low-power consumption, while delivering outstanding computational performance and exceptional system response to interrupts.

Its features include the following:

- ARMv7-M architecture optimized for small-footprint embedded applications
- Arm Thumb®-2 mixed 16- and 32-bit instruction set delivers the high performance expected of a 32-bit Arm core in a compact memory size
- Fast code execution permits increased sleep mode time
- Deterministic, high-performance interrupt handling for time-critical applications
- Single-cycle multiply instruction and hardware divide
- Hardware division and fast digital-signal-processing oriented multiply accumulate
- Saturating arithmetic for signal processing
- IEEE 754-compliant single-precision Floating Point Unit (FPU)
- Memory Protection Unit (MPU) for safety-critical applications
- Full debug with data matching for watchpoint generation
 - Data Watchpoint and Trace Unit (DWT)
 - JTAG Debug Access Port (DAP)
 - Flash Patch and Breakpoint Unit (FPB)
- Trace support reduces the number of pins required for debugging and tracing
 - Instrumentation Trace Macrocell Unit (ITM)
 - Trace Port Interface Unit (TPIU) with asynchronous serial wire output (SWO)
- Optimized for single-cycle flash memory access
- Tightly connected to 8-KB 4-way random replacement cache for minimal active power consumption and wait states
- Ultra-low-power consumption with integrated sleep modes
- 48 MHz operation
- 1.25 DMIPS per MHz

9.3 Radio (RF Core)

The RF Core is a highly flexible and future proof radio module which contains an Arm Cortex-M0 processor that interfaces the analog RF and base-band circuitry, handles data to and from the system CPU side, and assembles the information bits in a given packet structure. The RF core offers a high level, command-based API to the main CPU that configurations and data are passed through. The Arm Cortex-M0 processor is not programmable by customers and is interfaced through the TI-provided RF driver that is included with the SimpleLink Software Development Kit (SDK).

The RF core can autonomously handle the time-critical aspects of the radio protocols, thus offloading the main CPU, which reduces power and leaves more resources for the user application. Several signals are also available to control external circuitry such as RF switches or range extenders autonomously.

A Packet Traffic Arbitrator (PTA) scheme is available for the managed coexistence of BLE and a co-located 2.4-GHz radio. This is based on 802.15.2 recommendations and common industry standards. The 3-wire coexistence interface has multiple modes of operation, encompassing different use cases and number of lines used for signaling. The radio acting as a slave is able to request access to the 2.4-GHz ISM band, and the master to grant it. Information about the request priority and TX or RX operation can also be conveyed.

The various physical layer radio formats are partly built as a software defined radio where the radio behavior is either defined by radio ROM contents or by non-ROM radio formats delivered in form of firmware patches with the SimpleLink SDKs. This allows the radio platform to be updated for support of future versions of standards even with over-the-air (OTA) updates while still using the same silicon.

9.3.1 Bluetooth 5.2 Low Energy

The RF Core offers full support for Bluetooth 5.2 Low Energy, including the high-speed 2-Mbps physical layer and the 500-kbps and 125-kbps long range PHYs (Coded PHY) through the TI provided Bluetooth 5.2 stack or through a high-level Bluetooth API. The Bluetooth 5.2 PHY and part of the controller are in radio and system ROM, providing significant savings in memory usage and more space available for applications.

The new high-speed mode allows data transfers up to 2 Mbps, twice the speed of Bluetooth 4.2 and five times the speed of Bluetooth 4.0, without increasing power consumption. In addition to faster speeds, this mode offers significant improvements for energy efficiency and wireless coexistence with reduced radio communication time.

Bluetooth 5.2 also enables unparalleled flexibility for adjustment of speed and range based on application needs, which capitalizes on the high-speed or long-range modes respectively. Data transfers are now possible at 2 Mbps, enabling development of applications using voice, audio, imaging, and data logging that were not previously an option using Bluetooth low energy. With high-speed mode, existing applications deliver faster responses, richer engagement, and longer battery life. Bluetooth 5.2 enables fast, reliable firmware updates.

9.3.2 802.15.4 (Thread, Zigbee, 6LoWPAN)

Through a dedicated IEEE radio API, the RF Core supports the 2.4-GHz IEEE 802.15.4-2011 physical layer (2 Mcps per second Offset-QPSK with DSSS 1:8), used in Thread, Zigbee, and 6LoWPAN protocols. The 802.15.4 PHY and MAC are in radio and system ROM. TI also provides royalty-free protocol stacks for Thread and Zigbee as part of the SimpleLink SDK, enabling a robust end-to-end solution.

9.4 Memory

The up to 352-KB nonvolatile (Flash) memory provides storage for code and data. The flash memory is in-system programmable and erasable. The last flash memory sector must contain a Customer Configuration section (CCFG) that is used by boot ROM and TI provided drivers to configure the device. This configuration is done through the `ccfg.c` source file that is included in all TI provided examples.

The ultra-low leakage system static RAM (SRAM) is split into up to five 16-KB blocks and can be used for both storage of data and execution of code. Retention of SRAM contents in Standby power mode is enabled by default and included in Standby mode power consumption numbers. Parity checking for detection of bit errors in memory is built-in, which reduces chip-level soft errors and thereby increases reliability. System SRAM is always initialized to zeroes upon code execution from boot.

To improve code execution speed and lower power when executing code from nonvolatile memory, a 4-way nonassociative 8-KB cache is enabled by default to cache and prefetch instructions read by the system CPU. The cache can be used as a general-purpose RAM by enabling this feature in the Customer Configuration Area (CCFG).

There is a 4-KB ultra-low leakage SRAM available for use with the Sensor Controller Engine which is typically used for storing Sensor Controller programs, data and configuration parameters. This RAM is also accessible by the system CPU. The Sensor Controller RAM is not cleared to zeroes between system resets.

The ROM includes a TI-RTOS kernel and low-level drivers, as well as significant parts of selected radio stacks, which frees up flash memory for the application. The ROM also contains a serial (SPI and UART) bootloader that can be used for initial programming of the device.

9.5 Sensor Controller

The Sensor Controller contains circuitry that can be selectively enabled in both Standby and Active power modes. The peripherals in this domain can be controlled by the Sensor Controller Engine, which is a proprietary power-optimized CPU. This CPU can read and monitor sensors or perform other tasks autonomously; thereby significantly reducing power consumption and offloading the system CPU.

The Sensor Controller Engine is user programmable with a simple programming language that has syntax similar to C. This programmability allows for sensor polling and other tasks to be specified as sequential algorithms rather than static configuration of complex peripheral modules, timers, DMA, register programmable state machines, or event routing.

The main advantages are:

- Flexibility - data can be read and processed in unlimited manners while still [ensuring ultra-low power](#)
- 2 MHz low-power mode enables lowest possible handling of digital sensors
- Dynamic reuse of hardware resources
- 40-bit accumulator supporting multiplication, addition and shift
- Observability and debugging options

[Sensor Controller Studio](#) is used to write, test, and debug code for the Sensor Controller. The tool produces C driver source code, which the System CPU application uses to control and exchange data with the Sensor Controller. Typical use cases may be (but are not limited to) the following:

- Read analog sensors using integrated ADC or comparators
- Interface digital sensors using GPIOs, SPI, UART, or I²C (UART and I²C are bit-banged)
- Capacitive sensing
- Waveform generation
- Very low-power pulse counting (flow metering)
- Key scan

The peripherals in the Sensor Controller include the following:

- The low-power clocked comparator can be used to wake the system CPU from any state in which the comparator is active. A configurable internal reference DAC can be used in conjunction with the comparator. The output of the comparator can also be used to trigger an interrupt or the ADC.
- Capacitive sensing functionality is implemented through the use of a constant current source, a time-to-digital converter, and a comparator. The continuous time comparator in this block can also be used as a higher-accuracy alternative to the low-power clocked comparator. The Sensor Controller takes care of baseline tracking, hysteresis, filtering, and other related functions when these modules are used for capacitive sensing.
- The ADC is a 12-bit, 200-ksamples/s ADC with eight inputs and a built-in voltage reference. The ADC can be triggered by many different sources including timers, I/O pins, software, and comparators.
- The analog modules can connect to up to eight different GPIOs
- Dedicated SPI master with up to 6 MHz clock speed

The peripherals in the Sensor Controller can also be controlled from the main application processor.

9.6 Cryptography

The CC2652RB device comes with a wide set of modern cryptography-related hardware accelerators, drastically reducing code footprint and execution time for cryptographic operations. It also has the benefit of being lower power and improves availability and responsiveness of the system because the cryptography operations runs in a background hardware thread.

Together with a large selection of open-source cryptography libraries provided with the Software Development Kit (SDK), this allows for secure and future proof IoT applications to be easily built on top of the platform. The hardware accelerator modules are:

- **True Random Number Generator (TRNG)** module provides a true, nondeterministic noise source for the purpose of generating keys, initialization vectors (IVs), and other random number requirements. The TRNG is built on 24 ring oscillators that create unpredictable output to feed a complex nonlinear-combinatorial circuit.
- **Secure Hash Algorithm 2 (SHA-2)** with support for SHA224, SHA256, SHA384, and SHA512
- **Advanced Encryption Standard (AES)** with 128 and 256 bit key lengths
- **Public Key Accelerator** - Hardware accelerator supporting mathematical operations needed for elliptic curves up to 512 bits and RSA key pair generation up to 1024 bits.

Through use of these modules and the TI provided cryptography drivers, the following capabilities are available for an application or stack:

- **Key Agreement Schemes**
 - Elliptic curve Diffie–Hellman with static or ephemeral keys (ECDH and ECDHE)
 - Elliptic curve Password Authenticated Key Exchange by Juggling (ECJ-PAKE)
- **Signature Generation**
 - Elliptic curve Diffie-Hellman Digital Signature Algorithm (ECDSA)
- **Curve Support**
 - Short Weierstrass form (full hardware support), such as:
 - NIST-P224, NIST-P256, NIST-P384, NIST-P521
 - Brainpool-256R1, Brainpool-384R1, Brainpool-512R1
 - secp256r1
 - Montgomery form (hardware support for multiplication), such as:
 - Curve25519
- **SHA2 based MACs**
 - HMAC with SHA224, SHA256, SHA384, or SHA512
- Block cipher mode of operation
 - AESCCM
 - AESGCM
 - AESECB
 - AESCBC
 - AESCBC-MAC
- **True random number generation**

Other capabilities, such as RSA encryption and signatures as well as Edwards type of elliptic curves such as Curve1174 or Ed25519, can also be implemented using the provided hardware accelerators but are not part of the TI SimpleLink SDK for the CC2652RB device.

9.7 Timers

A large selection of timers are available as part of the CC2652RB device. These timers are:

- **Real-Time Clock (RTC)**

A 70-bit 3-channel timer running on the 32 kHz low frequency system clock (SCLK_LF)

This timer is available in all power modes except Shutdown. The timer can be calibrated to compensate for frequency drift when using the LF RCOSC as the low frequency system clock. If an external LF clock with frequency different from 32.768 kHz is used, the RTC tick speed can be adjusted to compensate for this. When using TI-RTOS, the RTC is used as the base timer in the operating system and should thus only be accessed through the kernel APIs such as the Clock module. The real time clock can also be read by the Sensor Controller Engine to timestamp sensor data and also has dedicated capture channels. By default, the RTC halts when a debugger halts the device.

- **General Purpose Timers (GPTIMER)**

The four flexible GPTIMERS can be used as either 4× 32 bit timers or 8× 16 bit timers, all running on up to 48 MHz. Each of the 16- or 32-bit timers support a wide range of features such as one-shot or periodic counting, pulse width modulation (PWM), time counting between edges and edge counting. The inputs and outputs of the timer are connected to the device event fabric, which allows the timers to interact with signals such as GPIO inputs, other timers, DMA and ADC. The GPTIMERS are available in Active and Idle power modes.

- **Sensor Controller Timers**

The Sensor Controller contains 3 timers:

AUX Timer 0 and 1 are 16-bit timers with a 2^N prescaler. Timers can either increment on a clock or on each edge of a selected tick source. Both one-shot and periodical timer modes are available.

AUX Timer 2 is a 16-bit timer that can operate at 24 MHz, 2 MHz or 32 kHz independent of the Sensor Controller functionality. There are 4 capture or compare channels, which can be operated in one-shot or periodical modes. The timer can be used to generate events for the Sensor Controller Engine or the ADC, as well as for PWM output or waveform generation.

- **Radio Timer**

A multichannel 32-bit timer running at 4 MHz is available as part of the device radio. The radio timer is typically used as the timing base in wireless network communication using the 32-bit timing word as the network time. The radio timer is synchronized with the RTC by using a dedicated radio API when the device radio is turned on or off. This ensures that for a network stack, the radio timer seems to always be running when the radio is enabled. The radio timer is in most cases used indirectly through the trigger time fields in the radio APIs and should only be used when running the accurate 48 MHz high frequency crystal is the source of SCLK_HF.

- **Watchdog timer**

The watchdog timer is used to regain control if the system operates incorrectly due to software errors. It is typically used to generate an interrupt to and reset of the device for the case where periodic monitoring of the system components and tasks fails to verify proper functionality. The watchdog timer runs on a 1.5 MHz clock rate and cannot be stopped once enabled. The watchdog timer pauses to run in Standby power mode and when a debugger halts the device.

9.8 Serial Peripherals and I/O

The SSIs are synchronous serial interfaces that are compatible with SPI, MICROWIRE, and TI's synchronous serial interfaces. The SSIs support both SPI master and slave up to 4 MHz. The SSI modules support configurable phase and polarity.

The UARTs implement universal asynchronous receiver and transmitter functions. They support flexible baud-rate generation up to a maximum of 3 Mbps.

The I²S interface is used to handle digital audio and can also be used to interface pulse-density modulation microphones (PDM).

The I²C interface is also used to communicate with devices compatible with the I²C standard. The I²C interface can handle 100 kHz and 400 kHz operation, and can serve as both master and slave.

The I/O controller (IOC) controls the digital I/O pins and contains multiplexer circuitry to allow a set of peripherals to be assigned to I/O pins in a flexible manner. All digital I/Os are interrupt and wake-up capable, have a programmable pullup and pulldown function, and can generate an interrupt on a negative or positive edge (configurable). When configured as an output, pins can function as either push-pull or open-drain. Five GPIOs have high-drive capabilities, which are marked in **bold** in [セクション 7](#). All digital peripherals can be connected to any digital pin on the device.

For more information, see the [CC13x2, CC26x2 SimpleLink™ Wireless MCU Technical Reference Manual](#).

9.9 Battery and Temperature Monitor

A combined temperature and battery voltage monitor is available in the CC2652RB device. The battery and temperature monitor allows an application to continuously monitor on-chip temperature and supply voltage and respond to changes in environmental conditions as needed. The module contains window comparators to interrupt the system CPU when temperature or supply voltage go outside defined windows. These events can also be used to wake up the device from Standby mode through the Always-On (AON) event fabric.

9.10 μ DMA

The device includes a direct memory access (μ DMA) controller. The μ DMA controller provides a way to offload data-transfer tasks from the system CPU, thus allowing for more efficient use of the processor and the available bus bandwidth. The μ DMA controller can perform a transfer between memory and peripherals. The μ DMA controller has dedicated channels for each supported on-chip module and can be programmed to automatically perform transfers between peripherals and memory when the peripheral is ready to transfer more data.

Some features of the μ DMA controller include the following (this is not an exhaustive list):

- Highly flexible and configurable channel operation of up to 32 channels
- Transfer modes: memory-to-memory, memory-to-peripheral, peripheral-to-memory, and peripheral-to-peripheral
- Data sizes of 8, 16, and 32 bits
- Ping-pong mode for continuous streaming of data

9.11 Debug

The on-chip debug support is done through a dedicated cJTAG (IEEE 1149.7) or JTAG (IEEE 1149.1) interface. The device boots by default into cJTAG mode and must be reconfigured to use 4-pin JTAG.

9.12 Power Management

To minimize power consumption, the CC2652RB supports a number of power modes and power management features (see [表 9-1](#)).

表 9-1. Power Modes

MODE	SOFTWARE CONFIGURABLE POWER MODES				RESET PIN HELD
	ACTIVE	IDLE	STANDBY	SHUTDOWN	
CPU	Active	Off	Off	Off	Off
Flash	On	Available	Off	Off	Off
SRAM	On	On	Retention	Off	Off
Supply System	On	On	Duty Cycled	Off	Off
Register and CPU retention	Full	Full	Partial	No	No
SRAM retention	Full	Full	Full	No	No
48 MHz high-speed clock (SCLK_HF)	BAW or RCOSC_HF	BAW or RCOSC_HF	Off	Off	Off
2 MHz medium-speed clock (SCLK_MF)	RCOSC_MF	RCOSC_MF	Available	Off	Off
32 kHz low-speed clock (SCLK_LF)	XOSC_LF or RCOSC_LF	XOSC_LF or RCOSC_LF	XOSC_LF or RCOSC_LF	Off	Off
Peripherals	Available	Available	Off	Off	Off
Sensor Controller	Available	Available	Available	Off	Off
Wake-up on RTC	Available	Available	Available	Off	Off
Wake-up on pin edge	Available	Available	Available	Available	Off
Wake-up on reset pin	On	On	On	On	On
Brownout detector (BOD)	On	On	Duty Cycled	Off	Off
Power-on reset (POR)	On	On	On	Off	Off
Watchdog timer (WDT)	Available	Available	Paused	Off	Off

In **Active** mode, the application system CPU is actively executing code. Active mode provides normal operation of the processor and all of the peripherals that are currently enabled. The system clock can be any available clock source (see [表 9-1](#)).

In **Idle** mode, all active peripherals can be clocked, but the Application CPU core and memory are not clocked and no code is executed. Any interrupt event brings the processor back into active mode.

In **Standby** mode, only the always-on (AON) domain is active. An external wake-up event, RTC event, or Sensor Controller event is required to bring the device back to active mode. MCU peripherals with retention do not need to be reconfigured when waking up again, and the CPU continues execution from where it went into standby mode. All GPIOs are latched in standby mode.

In **Shutdown** mode, the device is entirely turned off (including the AON domain and Sensor Controller), and the I/Os are latched with the value they had before entering shutdown mode. A change of state on any I/O pin defined as a *wake from shutdown pin* wakes up the device and functions as a reset trigger. The CPU can differentiate between reset in this way and reset-by-reset pin or power-on reset by reading the reset status register. The only state retained in this mode is the latched I/O state and the flash memory contents.

The Sensor Controller is an autonomous processor that can control the peripherals in the Sensor Controller independently of the system CPU. This means that the system CPU does not have to wake up, for example to perform an ADC sampling or poll a digital sensor over SPI, thus saving both current and wake-up time that would otherwise be wasted. The [Sensor Controller Studio](#) tool enables the user to program the Sensor Controller, control its peripherals, and wake up the system CPU as needed. All Sensor Controller peripherals can also be controlled by the system CPU.

注

The power, RF and clock management for the CC2652RB device require specific configuration and handling by software for optimized performance. This configuration and handling is implemented in the TI-provided drivers that are part of the CC2652RB software development kit (SDK). Therefore, TI highly recommends using this software framework for all application development on the device. The complete [SDK](#) with TI-RTOS (optional), device drivers, and examples are offered free of charge in source code.

9.13 Clock Systems

The CC2652RB device has several internal system clocks.

The 48 MHz SCLK_HF is used as the main system (MCU and peripherals) clock. This can be driven by the internal 48 MHz RC Oscillator (RCOSC_HF), the internal BAW resonator, or an external 48 MHz crystal (XOSC_HF). Radio operation requires either the internal BAW resonator or an external 48 MHz crystal.

SCLK_MF is an internal 2 MHz clock that is used by the Sensor Controller in low-power mode and also for internal power management circuitry. The SCLK_MF clock is always driven by the internal 2 MHz RC Oscillator (RCOSC_MF).

The BAW oscillator clock frequency is actively compensated by the modem internal firmware to ensure frequency stability over temperature, voltage and device lifetime. Every time the PLL is tuned (wakeup of radio from idle/standby or tuned to a difference frequency) the modem firmware considers the BAW device characteristics stored on the device along with current temperature and voltage conditions and configures the PLL to compensate accordingly. The RF frequency accuracy around the desired center frequency is +/-40ppm across temperature.

SCLK_LF is the 32.768 kHz internal low-frequency system clock. It can be used by the Sensor Controller for ultra-low-power operation and is also used for the RTC and to synchronize the radio timer before or after Standby power mode. SCLK_LF can be driven by the internal 32.8 kHz RC Oscillator (RCOSC_LF), a 32.768 kHz watch-type crystal, the internal BAW resonator, an external 48 MHz crystal, or a clock input on any digital IO.

When using a crystal or the internal RC oscillator, the device can output the 32 kHz SCLK_LF signal to other devices, thereby reducing the overall system cost.

9.14 Network Processor

Depending on the product configuration, the CC2652RB device can function as a wireless network processor (WNP - a device running the wireless protocol stack with the application running on a separate host MCU), or as a system-on-chip (SoC) with the application and protocol stack running on the system CPU inside the device.

In the first case, the external host MCU communicates with the device using SPI or UART. In the second case, the application must be written according to the application framework supplied with the wireless protocol stack.

10 Application, Implementation, and Layout

注

以下のアプリケーション情報は、TI の製品仕様に含まれるものではなく、TI ではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくこととなります。また、お客様は自身の設計実装を検証テストすることで、システムの機能を確認する必要があります。

For general design guidelines and hardware configuration guidelines, refer to the [CC13xx/CC26xx Hardware Configuration and PCB Design Considerations Application Report](#).

10.1 Reference Designs

The following reference designs should be followed closely when implementing designs using the CC2652RB device.

Special attention must be paid to RF component placement, decoupling capacitors and DCDC regulator components, as well as ground connections for all of these.

Integrated matched filter-balun devices can be used both at sub-1 GHz frequencies and at 2.4 GHz for the low-power RF outputs. Refer to the "Integrated Passive Component" section in [CC13xx/CC26xx Hardware Configuration and PCB Design Considerations](#) for further information.

[CC26x2RBEM-7ID Design Files](#) The CC26x2RBEM-7ID reference design provides schematic, layout and production files for the characterization board used for deriving the performance number found in this document.

[CC2652RB LaunchPad™ Development Kit Design Files](#) The CC2652RB LaunchPad Design Files contain detailed schematics and layouts to build application specific boards using the CC2652RB device.

[Sub-1 GHz and 2.4 GHz Antenna Kit for LaunchPad™ Development Kit and SensorTag](#) The antenna kit allows real-life testing to identify the optimal antenna for your application. The antenna kit includes 16 antennas for frequencies from 169 MHz to 2.4 GHz, including:

- PCB antennas
- Helical antennas
- Chip antennas
- Dual-band antennas for 868 MHz and 915 MHz combined with 2.4 GHz

The antenna kit includes a JSC cable to connect to the Wireless MCU LaunchPad development kits and SensorTags.

11 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed as follows.

11.1 Tools and Software

The CC2652RB device is supported by a variety of software and hardware development tools.

Development Kit

[CC2652RB LaunchPad™ Development Kit](#)

The CC2652RB LaunchPad™ Development Kit enables development of high-performance wireless applications that benefit from low-power operation. The kit features the CC2652RB SimpleLink Wireless MCU, which allows you to quickly evaluate and prototype 2.4-GHz wireless Bluetooth 5 Low Energy, Zigbee and Thread, plus combinations of these. The kit works with the LaunchPad ecosystem, easily enabling additional functionality like sensors, display and more. The built-in EnergyTrace™ software is an energy-based code analysis tool that measures and displays the application's energy profile and helps to optimize it for ultra-low-power consumption. See [表 6-1](#) for guidance in selecting the correct device for single-protocol products.

Software

[SimpleLink™ CC13x2 and CC26x2 Software Development Kit](#)

The SimpleLink CC13x2 and CC26x2 Software Development Kit (SDK) provides a complete package for the development of Bluetooth-based applications for the CC2652RB wireless MCU. The SimpleLink CC13x2 and CC26x2 SDK is part of TI's SimpleLink MCU platform, offering a single development environment that delivers flexible hardware, software and tool options for customers developing wired and wireless applications. For more information about the SimpleLink MCU Platform, visit <https://www.ti.com/simplelink>.

Development Tools

Code Composer Studio™ Integrated Development Environment (IDE)

Code Composer Studio is an integrated development environment (IDE) that supports TI's Microcontroller and Embedded Processors portfolio. Code Composer Studio comprises a suite of tools used to develop and debug embedded applications. It includes an optimizing C/C++ compiler, source code editor, project build environment, debugger, profiler, and many other features. The intuitive IDE provides a single user interface taking you through each step of the application development flow. Familiar tools and interfaces allow users to get started faster than ever before. Code Composer Studio combines the advantages of the Eclipse® software framework with advanced embedded debug capabilities from TI resulting in a compelling feature-rich development environment for embedded developers.

CCS has support for all SimpleLink Wireless MCUs and includes support for EnergyTrace™ software (application energy usage profiling). A real-time object viewer plugin is available for TI-RTOS, part of the SimpleLink SDK.

Code Composer Studio is provided free of charge when used in conjunction with the XDS debuggers included on a LaunchPad Development Kit.

Code Composer Studio™ Cloud IDE

Code Composer Studio (CCS) Cloud is a web-based IDE that allows you to create, edit and build CCS and Energia™ projects. After you have successfully built your project, you can download and run on your connected LaunchPad. Basic debugging, including features like setting breakpoints and viewing variable values is now supported with CCS Cloud.

IAR Embedded Workbench® for Arm®

IAR Embedded Workbench® is a set of development tools for building and debugging embedded system applications using assembler, C and C++. It provides a completely integrated development environment that includes a project manager, editor, and build tools. IAR has support for all SimpleLink Wireless MCUs. It offers broad debugger support, including XDS110, IAR I-jet™ and Segger J-Link™. A real-time object viewer plugin is available for TI-RTOS, part of the SimpleLink SDK. IAR is also supported out-of-the-box on most software examples provided as part of the SimpleLink SDK.

A 30-day evaluation or a 32 KB size-limited version is available through iar.com.

SmartRF™ Studio

SmartRF™ Studio is a Windows® application that can be used to evaluate and configure SimpleLink Wireless MCUs from Texas Instruments. The application will help designers of RF systems to easily evaluate the radio at an early stage in the design process. It is especially useful for generation of configuration register values and for practical testing and debugging of the RF system. SmartRF Studio can be used either as a standalone application or together with applicable evaluation boards or debug probes for the RF device. Features of the SmartRF Studio include:

- Link tests - send and receive packets between nodes
- Antenna and radiation tests - set the radio in continuous wave TX and RX states
- Export radio configuration code for use with the TI SimpleLink SDK RF driver
- Custom GPIO configuration for signaling and control of external switches

Sensor Controller Studio

Sensor Controller Studio is used to write, test and debug code for the Sensor Controller peripheral. The tool generates a Sensor Controller Interface driver, which is a set of C source files that are compiled into the System CPU application. These source files also contain the Sensor Controller binary image and allow the System CPU application to control and exchange data with the Sensor Controller. Features of the Sensor Controller Studio include:

- Ready-to-use examples for several common use cases
- Full toolchain with built-in compiler and assembler for programming in a C-like programming language
- Provides rapid development by using the integrated sensor controller task testing and debugging functionality, including visualization of sensor data and verification of algorithms

CCS UniFlash

CCS UniFlash is a standalone tool used to program on-chip flash memory on TI MCUs. UniFlash has a GUI, command line, and scripting interface. CCS UniFlash is available free of charge.

11.1.1 SimpleLink™ Microcontroller Platform

The SimpleLink microcontroller platform sets a new standard for developers with the broadest portfolio of wired and wireless Arm® MCUs (System-on-Chip) in a single software development environment. Delivering flexible hardware, software and tool options for your IoT applications. Invest once in the SimpleLink software development kit and use throughout your entire portfolio. Learn more on ti.com/simplelink.

11.2 Documentation Support

To receive notification of documentation updates on data sheets, errata, application notes and similar, navigate to the device product folder on ti.com/product/CC2652RB. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

The current documentation that describes the MCU, related peripherals, and other technical collateral is listed as follows.

TI Resource Explorer

TI Resource Explorer

Software examples, libraries, executables, and documentation are available for your device and development board.

Errata

CC2652RB Silicon Errata

The silicon errata describes the known exceptions to the functional specifications for each silicon revision of the device and description on how to recognize a device revision.

Application Reports

All application reports for the CC2652RB device are found on the device product folder at: ti.com/product/CC2652RB/technicaldocuments.

Technical Reference Manual (TRM)

CC13x2, CC26x2 SimpleLink™ Wireless MCU TRM

The TRM provides a detailed description of all modules and peripherals available in the device family.

11.3 サポート・リソース

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11.6 用語集

TI 用語集 この用語集には、用語や略語の一覧および定義が記載されています。

12 Mechanical, Packaging, and Orderable Information

12.1 Packaging Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
CC2652RB1FRGZR	Active	Production	VQFN (RGZ) 48	2500 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	CC2652 RB1F
CC2652RB1FRGZR.A	Active	Production	VQFN (RGZ) 48	2500 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	CC2652 RB1F
CC2652RB1FRGZRG4	Active	Production	VQFN (RGZ) 48	2500 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	CC2652 RB1F
CC2652RB1FRGZRG4.A	Active	Production	VQFN (RGZ) 48	2500 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	CC2652 RB1F

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

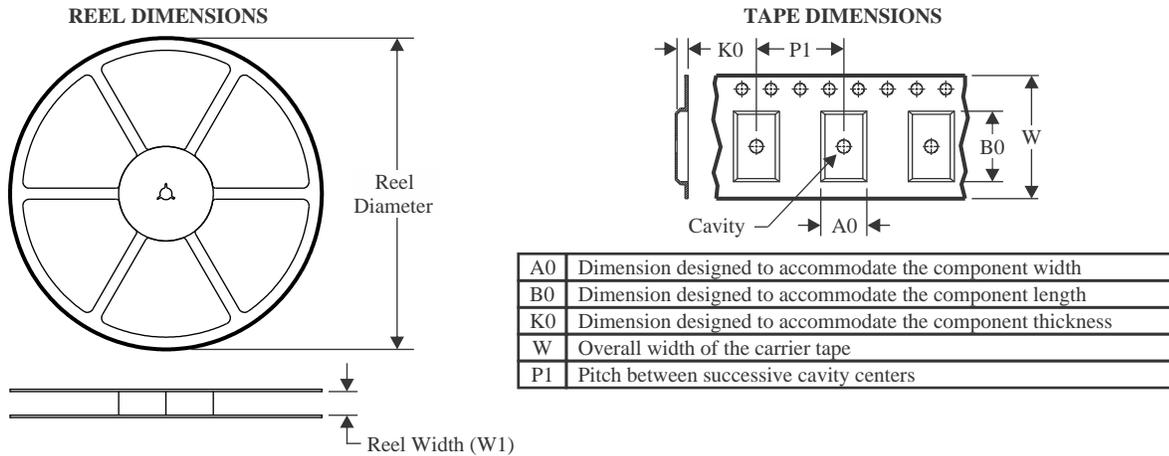
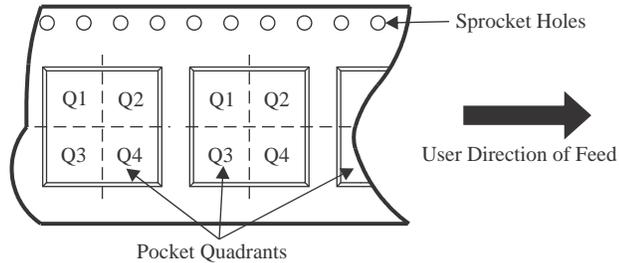
(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

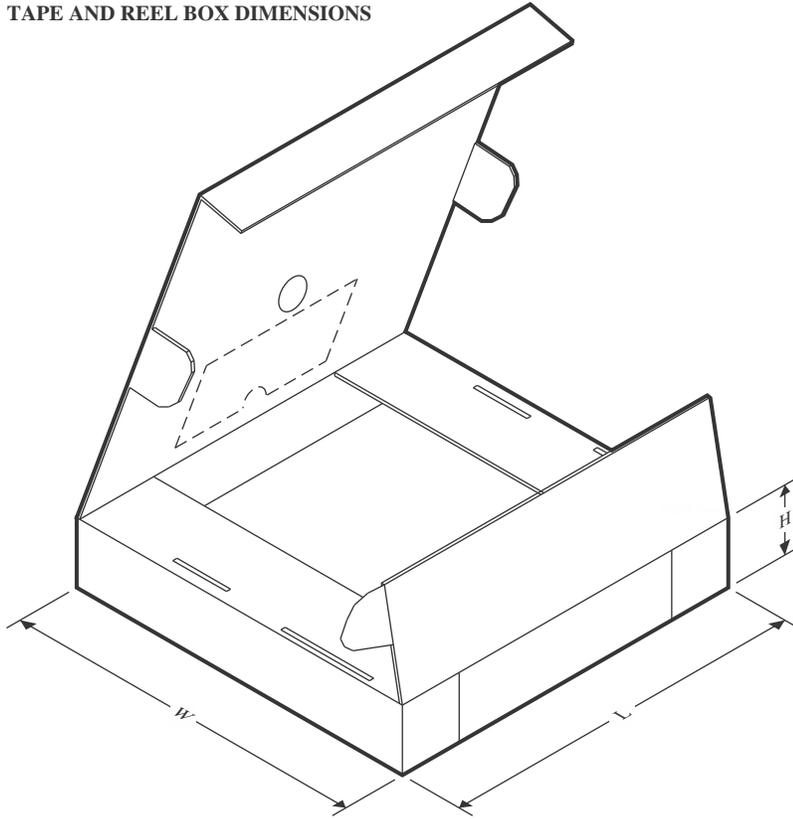
Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CC2652RB1FRGZR	VQFN	RGZ	48	2500	330.0	16.4	7.3	7.3	1.1	12.0	16.0	Q2
CC2652RB1FRGZRG4	VQFN	RGZ	48	2500	330.0	16.4	7.3	7.3	1.1	12.0	16.0	Q2

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CC2652RB1FRGZR	VQFN	RGZ	48	2500	336.6	336.6	31.8
CC2652RB1FRGZRG4	VQFN	RGZ	48	2500	336.6	336.6	31.8

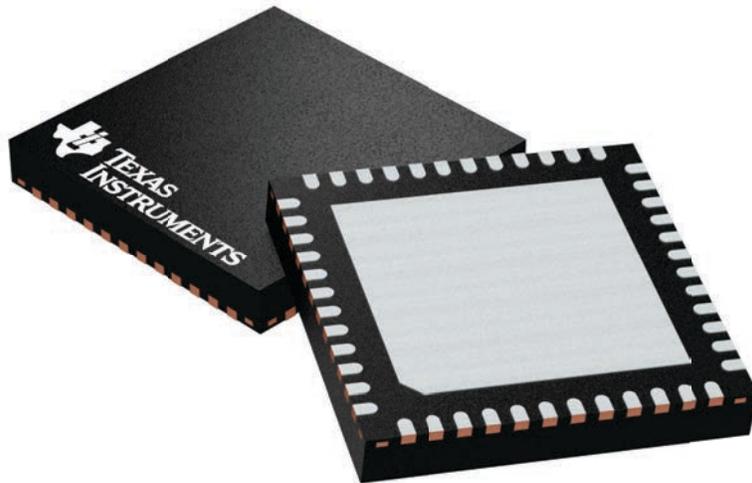
GENERIC PACKAGE VIEW

RGZ 48

VQFN - 1 mm max height

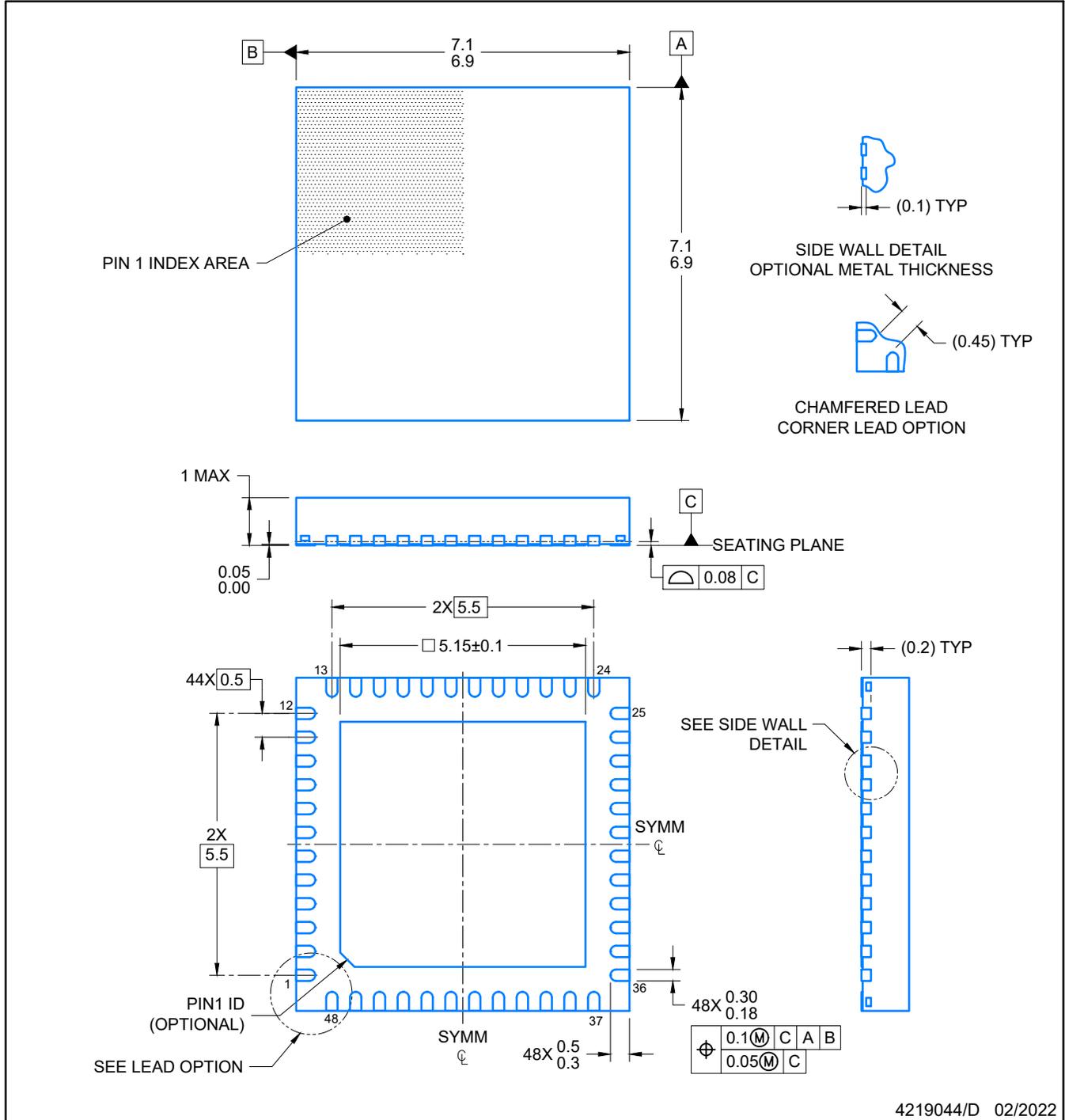
7 x 7, 0.5 mm pitch

PLASTIC QUADFLAT PACK- NO LEAD



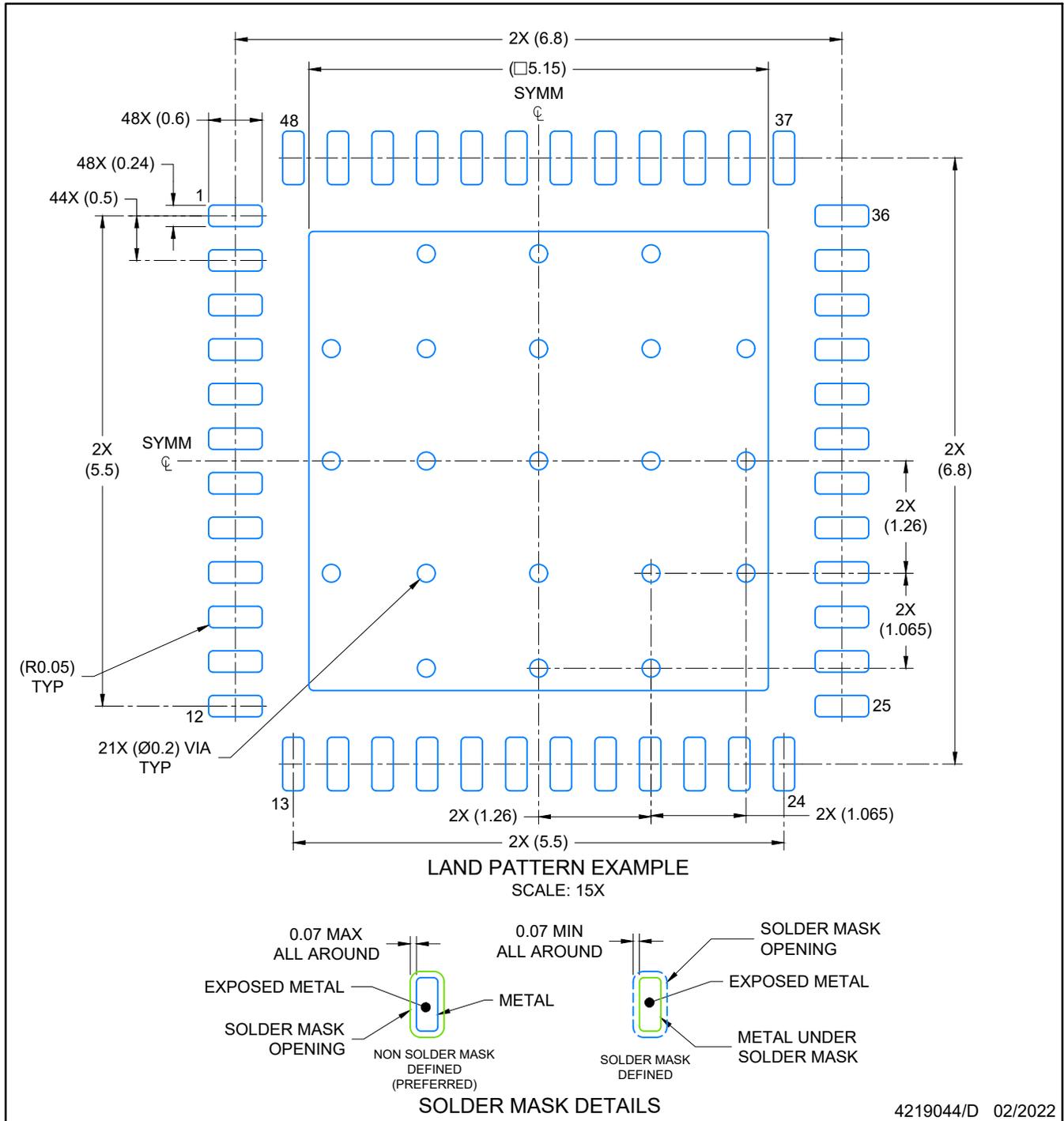
Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4224671/A



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



NOTES: (continued)

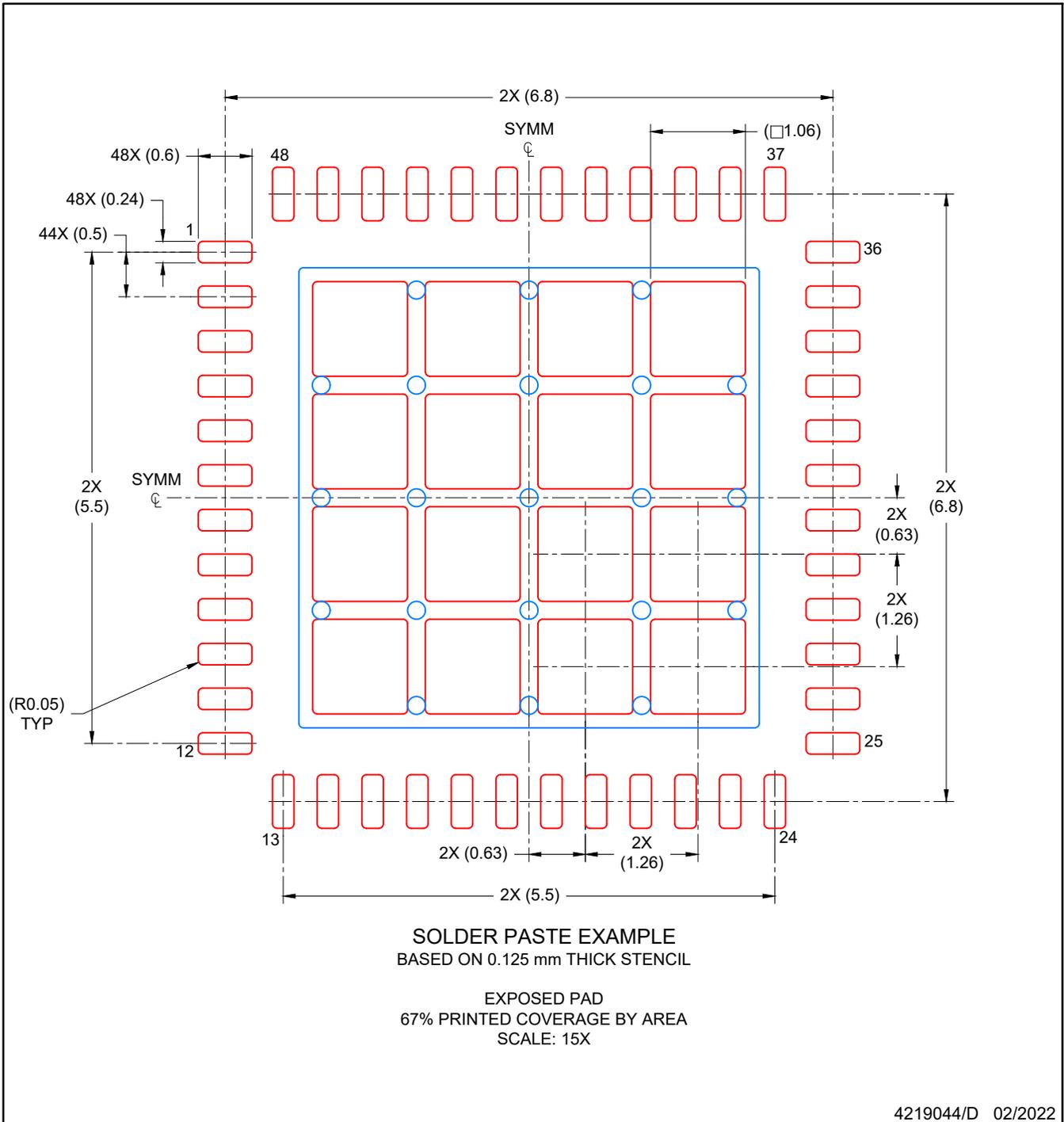
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RGZ0048A

VQFN - 1 mm max height

PLASTIC QUADFLAT PACK- NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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